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Freescale Semiconductor Data Sheet

Document Number: MSC7110

Rev. 11, 4/2008

MSC7110

Low-Cost 16-bit DSP with DDR Controller



- StarCore[®] SC1400 DSP extended core with one SC1400 DSP core, 64 Kbyte of internal SRAM M1 memory, 16 way 16 Kbyte instruction cache (ICache), four-entry write buffer, programmable interrupt controller (PIC), and low-power Wait and Stop processing modes.
- 8 Kbyte boot ROM.
- AHB-Lite crossbar switch that allows parallel data transfers
 between four master ports and six slave ports, where each port
 connects to an AHB-Lite bus; fixed or round robin priority
 programmable at each slave port; programmable bus parking at
 each slave port; low power mode.
- Internal PLL generates up to 266 MHz clock for the SC1400 core and up to 133 MHz for the crossbar switch, DMA channels, and other peripherals.
- Clock synthesis module provides predivision of PLL input clock; independent clocking of the internal timers and DDR module; programmable operation in the SC1400 low power Stop mode; independent shutdown of different regions of the device.
- Enhanced 16-bit wide host interface (HDI16) provides a glueless connection to industry-standard microcomputers, microprocessors, and DSPs and can also operate with an 8-bit host data bus, making if fully compatible with the DSP56300 HI08 from the external host side.
- DDR memory controller that supports byte enables for up to a 32-bit data bus; glueless interface to 133 MHz 14-bit page mode DDR-RAM; 14-bit external address bus supporting up to 1 Gbyte; and 16-bit or 32-bit external data bus.
- Programmable memory interface with independent read buffers, programmable predictive read feature for each buffer, and a write buffer.
- System control unit performs software watchdog timer function; includes programmable bus time-out monitors on AHB-Lite slave buses; includes bus error detection and programmable time-out monitors on AHB-Lite master buses; and has address out-of-range detection on each crossbar switch buses.
- Event port collects and counts important signal events including DMA and interrupt requests and trigger events such as interrupts, breakpoints, DMA transfers, or wake-up events; units operate independently, in sequence, or triggered externally; can be used standalone or with the OCE10.

- Multi-channel DMA controller with 32 time-multiplexed unidirectional channels, priority-based time-multiplexing between channels using 32 internal priority levels, fixed- or round-robin-priority operation, major-minor loop structure, and DONE or DRACK protocol from requesting units.
- One TDM module with independent receive and transmit, programmable sharing of frame sync and clock, programmable word size (8 or 16-bit), hardware-base A-law/μ-law conversion, up to 50 Mbps data rate, up to 128 channels, with glueless interface to E1/T1 frames and MVIP, SCAS, and H.110 buses.
- UART with full-duplex operation up to 5.0 Mbps.
- Up to 41 general-purpose input/output (GPIO) ports.
- I²C interface that allows booting from EEPROM devices up to 1 Mbyte.
- Two quad timer modules, each with sixteen configurable 16-bit timers.
- fieldBISTTM unit detects and provides visibility into unlikely field
 failures for systems with high availability to ensure structural
 integrity, that the device operates at the rated speed, is free from
 reliability defects, and reports diagnostics for partial or complete
 device inoperability.
- Standard JTAG interface allows easy integration to system firmware and internal on-chip emulation (OCE10) module.
- Optional booting external host via 8-bit or 16-bit access through the HDI16, I²C, or SPI using in the boot ROM to access serial SPI Flash/EEPROM devices; different clocking options during boot with the PLL on or off using a variety of input frequency ranges.





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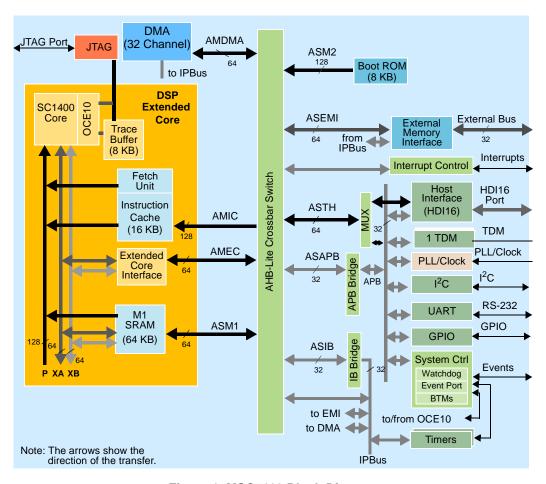


Figure 1. MSC7110 Block Diagram

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1 Pin Assignments

This section includes diagrams of the MSC7110 package ball grid array layouts and pinout allocation tables.

1.1 MAP-BGA Ball Layout Diagrams

Top and bottom views of the MAP-BGA package are shown in Figure 2 and Figure 3 with their ball location index numbers.

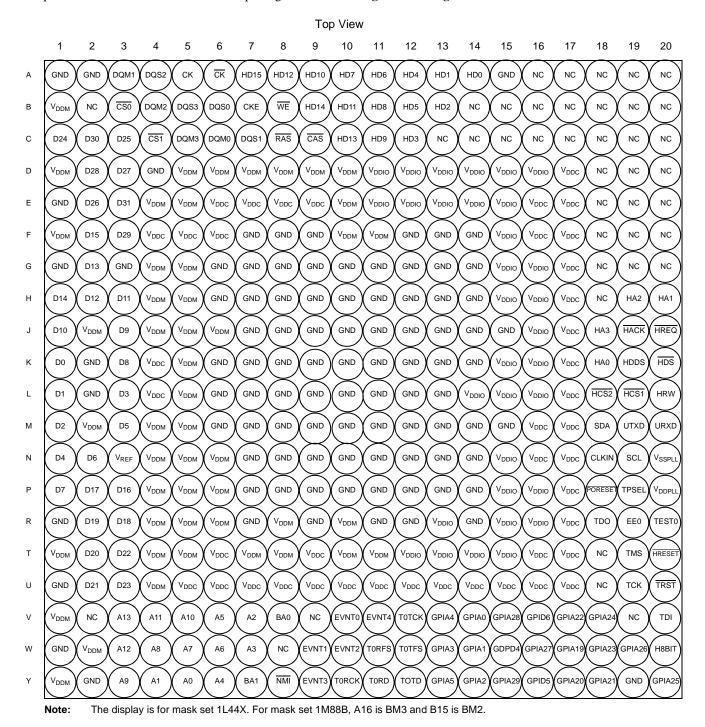


Figure 2. MSC7110 Molded Array Process-Ball Grid Array (MAP-BGA), Top View

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Bottom View 20 19 18 17 16 15 14 13 12 11 10 9 8 7 6 5 2 CK NC NC GND HD0 HD1 HD4 HD6 HD7 HD10 HD12 HD15 CK DQS2 DQM1 GND GND WE NC NC NC NC NC NC NC HD2 HD5 HD8 HD11 HD14 CKE DQS0 DQS3 DQM2 V_{DDM} В С NC NC NC HD3 HD9 HD13 CAS RAS DQS1 DQM0 DQM3 CS1 D24 NC NC GND D27 D28 D V_{DDIO} V_{DDIO} V_{DDIO} V_{DDM} V_{DDM} V_{DDM} V_{DDM} V_{DDM} D31 D26 Е GND NC GND GND GND GND GND GND D29 D15 F V_{DDIO} V_{DDM} V_{DDM} V_{DD} V_{DDM} G V_{DDIO} V_{DDIO} GND D14 GND Н GND GND GND GND GND V_{DD} V_{DDIO} V_{DDM} V_{DDM} V_{DDM} V_{DDM} HDDS GND GND GND GND GND GND GND GND GND D8 GND D0 HA0 V_{DD} V_{DDIO} V_{DDIO} V_{DDM} $V_{\mathsf{D}\mathsf{D}}$ K HCS1 HCS2 V_{DD} GND GND GND GND GND GND GND GND V_{DD} D1 L V_{DDIO} V_{DDIO} V_{DDIO} V_{DDM} URXD UTXD SDA GND D2 М GND GND GND GND GND GND GND GND Ν V_{DDIO} V_{DDM} V_{DDM} V_{REF} TPSFI GND GND GND GND GND GND GND GND D16 D17 D7 Р R TEST0 V_{DDIO} V_{DDIO} GND V_{DDM} V_{DDM} V_{DDM} GND V_{DDIO} TMS D20 Т V_{DD} V_{DDM} U V_{DD} V_{DDM} NC NC GPIA24 GPIA22 GPID6 GPIA28 GPIA0 GPIA4 TOTCK EVNT4 EVNT0 BA0 A2 A5 A10 A11 A13 ٧ V_{DDM}

Note: The display is for mask set 1L44X. For mask set 1M88B, A16 is BM3 and B15 is BM2.

GPIA3

GPIA5

TOTFS

TOTD

GPIA1

GPIA2

GPIA23

W

H8BIT

GPIA19

GPIA20

GPIA27

GPID5

GDPD4

GPIA29

Figure 3. MSC7110 Molded Array Process-Ball Grid Array (MAP-BGA), Bottom View

TORFS

T0RD

EVNT2

A6

Α8

 V_{DDM}

GND

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1.2 Signal List By Ball Location

Table 1 lists the signals sorted by ball number and configuration.

Table 1. MSC7110 Signals by Ball Designator

	Signal Names								
Number		Hardware Controlled							
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate			
A1			ND						
A2			G	ND					
А3			DC	QM1					
A4			DO	QS2					
A5			C	K					
A6			C	<u>K</u>					
A7		GPIC7		GPOC7	н	D15			
A8		GPIC4		GPOC4	н	D12			
A9		GPIC2		GPOC2	Н	D10			
A10		rese	rved		Н	ID7			
A11		rese	rved		Н	ID6			
A12		rese	rved		HD4				
A13		rese	rved		HD1				
A14		rese	rved		Н	ID0			
A15			G	ND					
A16 (1L44X)			N	IC					
A16 (1M88B)	BM3	GP	ID8	GPOD7	rese	erved			
A17			N	IC					
A18			N	IC					
A19			N	IC					
A20			N	IC					
B1			V _E	DDM					
B2			N	IC					
В3			C	S0					
B4			DC	QM2					
B5			DO	QS3					
B6			DC	QS0					
В7			С	KE					
B8			V	VE					
В9		GPIC6		GPOC6	HI	D14			
B10		GPIC3		GPOC3	HI	D11			
B11		GPIC0		GPOC0	Н	ID8			
B12		rese	rved		Н	ID5			
B13		rese	rved		Н	ID2			
B14			٨	IC					
B15 (1L44X)			N	IC					

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Pin Assignments

Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names									
Number		S	oftware Controlle	ed	Hardware	Controlled				
rambo	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
B15 (1M88B)	BM2	GP	ID7	GPOD7	res	erved				
B16			N	С						
B17			N	C						
B18			Ν	C						
B19			Ν	C						
B20			N	C						
C1			D	24						
C2			D	30						
C3			D	25						
C4			C	S1						
C5			DC	M3						
C6			DC	NM0						
C7			DC)S1						
C8			R	AS						
C9			C	AS						
C10		GPIC5		GPOC5	HD13					
C11		GPIC1		GPOC1	F	ID9				
C12		rese	rved		F	ID3				
C13			N	C						
C14			N	C						
C15			N	С						
C16			N	С						
C17			N	С						
C18			N	C						
C19			N	C						
C20			N	C						
D1			V _D	DM						
D2			D	28						
D3			D	27						
D4				ND						
D5				DM						
D6			V _D	DM						
D7			V _D	DM						
D8			V _D	DM						
D9			V _D	DM						
D10			V _D	DM						
D11			V_D	DIO						
D12			V_{D}	DIO						

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Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names									
Number		Sc	oftware Controlle	ed	Hardware	Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
D13		V_{DDIO}								
D14		$V_{ extsf{DDIO}}$								
D15		V_{DDIO}								
D16			V _D	DIO						
D17			V	DDC						
D18			N	IC						
D19			N	IC						
D20			N	IC						
E1			G	ND						
E2			D	26						
E3			D	31						
E4			V _E	DDM						
E5			V _E	DDM						
E6			V _[DDC						
E7			V _[DDC						
E8			V	DDC						
E9			V _[DDC						
E10			V	DDM						
E11			V _D	DIO						
E12			V _D	DIO						
E13			V _D	DIO						
E14			V _D	DIO						
E15			V _D	DIO						
E16			V _[DDC						
E17			V _[DDC						
E18				IC						
E19			N	IC						
E20			N	IC						
F1			V _E	DDM						
F2			D	15						
F3			D	29						
F4			V	DDC						
F5			V	DDC						
F6			V _[DDC						
F7			G	ND						
F8			G	ND						
F9			G	ND						
F10			V _E	DDM						

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Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names									
Number		Software Controlled				Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
F11		V_{DDM}								
F12		GND								
F13		GND								
F14			G	ND						
F15			V _D	DIO						
F16			V _[DDC						
F17			V _[DDC						
F18			١	IC						
F19			N	IC						
F20			N	IC						
G1			G	ND						
G2			D	13						
G3			G	ND						
G4			V _E	DDM						
G5				DDM						
G6				ND						
G7			G	ND						
G8			G	ND						
G9			G	ND						
G10			G	ND						
G11			G	ND						
G12			G	ND						
G13			G	ND						
G14			G	ND						
G15			V _D	DIO						
G16				DIO						
G17				DDC						
G18				IC						
G19			N	IC						
G20			N	IC						
H1			D	14						
H2			D	12						
H3			D	11						
H4			V _E	DDM						
H5				DDM						
H6				ND						
H7			G	ND						
H8			G	ND						

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Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names									
Number		S	oftware Controlle	ed	Hardware Controlled					
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
H9			GI	ND						
H10			ND							
H11			GI	ND						
H12			GI	ND						
H13			GI	ND						
H14			GI	ND						
H15			V_{D}	DIO						
H16			V_{D}	DIO						
H17			V _E	DDC						
H18			N	С						
H19		rese	rved		Н	A2				
H20		rese	Н	A1						
J1										
J2			V _D	DDM						
J3			С	9						
J4			V _D	DDM						
J5			V _D	DDM						
J6			V _D	DDM						
J7			GI	ND						
J8			GI	ND						
J9			GI	ND						
J10			GI	ND						
J11			GI	ND						
J12			GI	ND						
J13			GI	ND						
J14			GI	ND						
J15			GI	ND						
J16			V_{D}	DIO						
J17			V _E	DDC						
J18 (1L44X)		rese	rved		Н	A3				
J18 (1M88B)		GPIC11		GPOC11	Н	A3				
J19		rese	rved		HACK/HACK	or HRRQ/HRRQ				
J20	HDSP		reserved		HREQ/HREQ	or HTRQ/HTRQ				
K1			Г	00						
K2			GI	ND						
K3			Г	8						
K4			V _E	DDC						
K5			V _C	DDM						

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Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names									
Number		s	Software Controlled			Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
K6			GI	ND						
K7			GI	ND						
K8			GI	ND						
K9			GI	ND						
K10			GI	ND						
K11			GI	ND						
K12			GI	ND						
K13			GI	ND						
K14			GI	ND						
K15			V_{D}	DIO						
K16			V_{D}	DIO						
K17	V _{DDC}									
K18		rese	rved		HA0					
K19		rese	rved		НС	DDS				
K20		rese	rved		HDS/HDS o	or HWR/HWR				
L1			C)1						
L2			GI	ND						
L3			С	3						
L4			V _C	DDC						
L5			V _D	DDM						
L6				ND						
L7			GI	ND						
L8			GI	ND						
L9			GI	ND						
L10			GI	ND						
L11			GI	ND						
L12			GI	ND						
L13			GI	ND						
L14			V_{D}	DIO						
L15				DIO						
L16				DIO						
L17				DDC						
L18 (1L44X)		rese	rved		HCS2	/HCS2				
L18 (1M88B)		GPIB11		GPOB11	HCS2	/HCS2				
L19		rese	rved		HCS1	/HCS1				
L20		rese	rved		HRW or	HRD/HRD				
M1)2						
M2			V _C	DDM						

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Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names									
Number		Software Controlled				Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
M3			С	05						
M4		V_{DDM}								
M5		V_{DDM}								
M6			GI	ND						
M7			GI	ND						
M8			GI	ND						
M9			GI	ND						
M10			GI	ND						
M11			GI	ND						
M12			GI	ND						
M13			GI	ND						
M14			GI	ND						
M15			GI	ND						
M16			V _E	DDC						
M17	V _{DDC}									
M18	GPI	A14	IRQ15	GPOA14	S	DA				
M19	GPI	A12	ĪRQ3	GPOA12	U	ΓXD				
M20	GPI	A13	ĪRQ2	GPOA13	UF	RXD				
N1			С)4						
N2			С	06						
N3			V _F	REF						
N4			V _D	DDM						
N5			V _D	DDM						
N6			V _D	DDM						
N7			GI	ND						
N8			GI	ND						
N9			GI	ND						
N10			GI	ND						
N11			GI	ND						
N12			GI	ND						
N13			GI	ND						
N14				ND						
N15			V_D	DIO						
N16			V	DDC						
N17	N17 V _{DDC}									
N18			CL	KIN						
N19	GPI	A15	IRQ14	GPOA15	S	CL				

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Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names									
Number		Sc	oftware Controlle	ed	Hardware	Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
P1			1	07						
P2			D	17						
P3			D	16						
P4			V _E	DDM						
P5			V	DDM						
P6			V	DDM						
P7				ND						
P8			G	ND						
P9			G	ND						
P10			G	ND						
P11			G	ND						
P12			G	ND						
P13			G	ND						
P14	GND									
P15			V _D	DIO						
P16				DIO						
P17				DDC						
P18				ESET						
P19			TP	SEL						
P20			V_{DI}	OPLL						
R1			G	ND						
R2			D	19						
R3			D	18						
R4			V _E	DDM						
R5		V _{DDM}								
R6	V _{DDM}									
R7		GND								
R8		V_{DDM}								
R9			G	ND						
R10			V	DDM						
R11			G	ND						
R12			G	ND						
R13			V _D	DIO						
R14				ND						
R15			V _D	DIO						
R16			V _D	DIO						
R17				DDC						
R18				00						

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Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names								
Number		Sc	oftware Controll	ed	Hardware	Controlled			
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate			
R19		reserved EE0/DBRE							
R20		TEST0							
T1			V _I	DDM					
T2			D	20					
Т3			D	22					
T4			V _I	DDM					
T5				DDM					
Т6			V _I	DDC					
T7			V _I	DDM					
Т8			V _I	DDM					
Т9				DDC					
T10				DDM					
T11				DDM					
T12			V _E	DDIO					
T13				DDIO					
T14				DDIO					
T15				DDIO					
T16				DDC					
T17			VI	DDC					
T18				IC					
T19			T	MS					
T20			HRI	SET					
U1			G	ND					
U2			D	21					
U3			D	23					
U4			V _I	DDM					
U5				DDC					
U6			VI	DDC					
U7			VI	DDC					
U8			VI	DDC					
U9			V _I	DDC					
U10				DDC					
U11			V _I	DDC					
U12				DDC					
U13			VI	DDC					
U14			VI	DDC					
U15			VI	DDC					
U16				DDC					

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Table 1. MSC7110 Signals by Ball Designator (continued)

	Signal Names									
Number		ed	Hardware Controlled							
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
U17			V _E	DDC						
U18				IC						
U19			T	CK						
U20			TF	RST						
V1			V _E	DDM						
V2			N	IC						
V3			А	13						
V4			А	11						
V5			А	10						
V6			A	1 5						
V7			A	\2						
V8			В	A0						
V9			Ν	IC						
V10		reser	ved	EVNT0						
V11	SWTE	GPIA16	ĪRQ12	GPOA16	EVI	NT4				
V12	GP	IA8	ĪRQ6	GPOA8	T0TCK					
V13	GP	IA4	ĪRQ1	GPOA4	rese	rved				
V14	GP	IA0	ĪRQ11	GPOA0	reserved					
V15	GPI	A28	ĪRQ17	GPOA28	reserved reserved					
V16		GPID6		GPOD6	reserved reserved					
V17	GPI	A22	ĪRQ22	GPOA22	reserved					
V18	GPI	A24	ĪRQ24	GPOA24	reserved					
V19			٨	IC						
V20			T	DI						
W1			G	ND						
W2			V	DDM						
W3				12						
W4				18						
W5										
W6			P	A6						
W7			P	A3						
W8			N	IC						
W9	GPI	A17	ĪRQ13	GPOA17	EVNT1	CLKO				
W10	ВМО	GPIC	C14	GPOC14	EVI	NT2				
W11	GPI	A10	ĪRQ5	GPOA10	TORFS					
W12	GP	IA7	ĪRQ7	GPOA7	TOTFS					
W13	GP	IA3	ĪRQ8	GPOA3	reserved					
W14	GP	IA1	IRQ10	GPOA1	reserved					

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ssignments

Table 1. MSC7110 Signals by Ball Designator (continued)

Number	Signal Names								
		S	ed	Hardware Controlled					
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate			
W15		GPID4		GPOD4	reserved	reserved			
W16	GPI	GPIA27		GPOA27	reserved	reserved			
W17	GPI	A19	IRQ19	GPOA19	rese	rved			
W18	GPI	A23	ĪRQ23	GPOA23	rese	rved			
W19	GPI	A26	ĪRQ26	GPOA26	rese	rved			
W20	H8BIT			reserved					
Y1			V _C	DDM					
Y2			G	ND					
Y3			P	1 9					
Y4			P	.1					
Y5			P	۸0					
Y6			A	.4					
Y7			В	A1					
Y8	rese	rved	NMI	reserved					
Y9	BM1	GPI	C15	GPOC15	EVI	NT3			
Y10	GPI	A11	ĪRQ4	GPOA11	TOF	CK			
Y11		GPIA9		GPOA9	TO	RD			
Y12		GPIA6		GPOA6	T0	TD			
Y13	GP	IA5	ĪRQ0	GPOA5	rese	rved			
Y14	GP	IA2	ĪRQ9	GPOA2	rese	rved			
Y15	GPI	A29	ĪRQ16	GPOA29	reserved	reserved			
Y16		GPID5		GPOD5	reserved	reserved			
Y17	GPI	A20	ĪRQ20	GPOA20	rese	rved			
Y18	GPI	A21	ĪRQ21	GPOA21	rese	rved			
Y19			G	ND					
Y20	GPI	A25	IRQ25	GPOA25	rese	rved			



Specifications

2 Specifications

This chapter covers power considerations, DC/AC electrical characteristics, and AC timing specifications. For additional information, see the *MSC711x Reference Manual*.

Note: The MSC7110 electrical specifications are preliminary and many are from design simulations. These specifications may not be fully tested or guaranteed at this early stage of the product life cycle. Finalized specifications will be published after thorough characterization and device qualifications have been completed.

2.1 Maximum Ratings

CAUTION

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, normal precautions should be taken to avoid exceeding maximum voltage ratings. Reliability is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or V_{DD}).

In calculating timing requirements, adding a maximum value of one specification to a minimum value of another specification does not yield a reasonable sum. A maximum specification is calculated using a worst case variation of process parameter values in one direction. The minimum specification is calculated using the worst case for the same parameters in the opposite direction. Therefore, a "maximum" value for a specification never occurs in the same device with a "minimum" value for another specification; adding a maximum to a minimum represents a condition that can never exist.

Table 2 describes the maximum electrical ratings for the MSC7110.

Table 2. Absolute Maximum Ratings

Rating	Symbol	Value	Unit
Core supply voltage	V _{DDC}	1.5	V
Memory supply voltage	V_{DDM}	4.0	V
PLL supply voltage	V _{DDPLL}	1.5	V
I/O supply voltage	V _{DDIO}	-0.2 to 4.0	V
Input voltage	V _{IN}	(GND – 0.2) to 4.0	V
Reference voltage	V _{REF}	4.0	V
Maximum operating temperature	T _J	105	°C
Minimum operating temperature	T _A	-40	°C
Storage temperature range	T _{STG}	-55 to +150	°C

Notes:

- 1. Functional operating conditions are given in Table 3.
- 2. Absolute maximum ratings are stress ratings only, and functional operation at the maximum is not guaranteed. Stress beyond the listed limits may affect device reliability or cause permanent damage.
- 3. Section 3.1, Thermal Design Considerations includes a formula for computing the chip junction temperature (T,j).

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2.2 Recommended Operating Conditions

Table 3 lists recommended operating conditions. Proper device operation outside of these conditions is not guaranteed.

Table 3. Recommended Operating Conditions

Rating	Symbol	Value	Unit
Core supply voltage	V _{DDC}	1.14 to 1.26	V
Memory supply voltage	V _{DDM}	2.38 to 2.63	V
PLL supply voltage	V _{DDPLL}	1.14 to 1.26	V
I/O supply voltage	V _{DDIO}	3.14 to 3.47	V
Reference voltage	V _{REF}	1.19 to 1.31	V
Operating temperature range	T _J T _A	maximum: 105 minimum: –40	ပ္

2.3 Thermal Characteristics

Table 4 describes thermal characteristics of the MSC7110 for the MAP-BGA package.

Table 4. Thermal Characteristics for MAP-BGA Package

		MAP-BGA		
Characteristic	Symbol	Natural Convection	200 ft/min (1 m/s) airflow	Unit
Junction-to-ambient ^{1, 2}	$R_{ heta JA}$	39	31	°C/W
Junction-to-ambient, four-layer board ^{1, 3}	$R_{ heta JA}$	23	20	°C/W
Junction-to-board ⁴	$R_{ heta JB}$	12		°C/W
Junction-to-case ⁵	R _{θJC}	7		°C/W
Junction-to-package-top ⁶	Ψ_{JT}	2		°C/W

Notes:

- Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal
- 2. Per SEMI G38-87 and JEDEC JESD51-2 with the single layer board horizontal.
- 3. Per JEDEC JESD51-6 with the board horizontal.
- 4. Thermal resistance between the die and the printed circuit board per JEDEC JESD 51-8. Board temperature is measured on the top surface of the board near the package.
- 5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
- 6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.

Section 3.1, Thermal Design Considerations explains these characteristics in detail.



Specifications

2.4 DC Electrical Characteristics

This section describes the DC electrical characteristics for the MSC7110.

Note: The leakage current is measured for nominal voltage values must vary in the same direction (for example, both V_{DDIO} and V_{DDC} vary by +2 percent or both vary by -2 percent).

Table 5. DC Electrical Characteristics

Characteristic	Symbol	Min	Typical	Max	Unit
Core and PLL voltage	V _{DDC} V _{DDPLL}	1.14	1.2	1.26	V
DRAM interface I/O voltage ¹	V_{DDM}	2.375	2.5	2.625	V
I/O voltage	V _{DDIO}	3.135	3.3	3.465	V
DRAM interface I/O reference voltage ²	V _{REF}	$0.49 \times V_{DDM}$	1.25	$0.51 \times V_{DDM}$	V
DRAM interface I/O termination voltage ³	VTT	V _{REF} - 0.04	V _{REF}	V _{REF} + 0.04	V
Input high CLKIN voltage	V _{IHCLK}	2.4	3.0	3.465	V
DRAM interface input high I/O voltage	V _{IHM}	V _{REF} + 0.28	V_{DDM}	V _{DDM} + 0.3	V
DRAM interface input low I/O voltage	V_{ILM}	-0.3	GND	V _{REF} – 0.18	V
Input leakage current, V _{IN} = V _{DDIO}	I _{IN}	-1.0	0.09	1	μA
V _{REF} input leakage current	I _{VREF}	_	_	5	μA
Tri-state (high impedance off state) leakage current, $V_{\rm IN} = V_{\rm DDIO}$	I _{OZ}	-1.0	0.09	1	μА
Signal low input current, V _{IL} = 0.4 V	ΙL	-1.0	0.09	1	μA
Signal high input current, V _{IH} = 2.0 V	I _H	-1.0	0.09	1	μA
Output high voltage, $I_{OH} = -2$ mA, except open drain pins	V _{OH}	2.0	3.0	_	V
Output low voltage, I _{OL} = 5 mA	V _{OL}	_	0	0.4	V
Typical core power ⁵ • at 200 MHz • at 266 MHz (mask set 1M88B only)	P _C		222 293		mW mW

Notes:

- 1. The value of V_{DDM} at the MSC7110 device must remain within 50 mV of V_{DDM} at the DRAM device at all times.
- V_{REF} must be equal to 50% of V_{DDM} and track V_{DDM} variations as measured at the receiver. Peak-to-peak noise must not exceed ±2% of the DC value.
- 3. V_{TT} is not applied directly to the MSC7110 device. It is the level measured at the far end signal termination. It should be equal to V_{RFF}. This rail should track variations in the DC level of V_{RFF}.
- Output leakage for the memory interface is measured with all outputs disabled, 0 V ≤ V_{OUT} ≤ V_{DDM}.
- The core power values were measured.using a standard EFR pattern at typical conditions (25°C, 200 MHz or 266 MHz, 1.2 V core).

Table 6 lists the DDR DRAM capacitance.

Table 6. DDR DRAM Capacitance

Parameter/Condition	Symbol	Max	Unit
Input/output capacitance: DQ, DQS	C _{IO}	30	pF
Delta input/output capacitance: DQ, DQS	C _{DIO}	30	pF

Note: These values were measured under the following conditions:

- $V_{DDM} = 2.5 V \pm 0.125 V$
- f = 1 MHz
- \bullet T_A = 25 $^{\circ}$ C
- $V_{OUT} = V_{DDM}/2$
- V_{OUT} (peak to peak) = 0.2 V

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2.5 AC Timings

This section presents timing diagrams and specifications for individual signals and parallel I/O outputs and inputs. All AC timings are based on a 30 pF load, except where noted otherwise, and a 50 Ω transmission line. For any additional pF, use the following equations to compute the delay:

Standard interface: 2.45 + (0.054 × C_{load}) ns
 DDR interface: 1.6 + (0.002 × C_{load}) ns

2.5.1 Clock and Timing Signals

The following tables describe clock signal characteristics. **Table 7** shows the maximum frequency values for internal (core, reference, and peripherals) and external (CLKO) clocks. You must ensure that maximum frequency values are not exceeded (see for the allowable ranges when using the PLL).

Table 7. Maximum Frequencies

Characteristic	Maximu	m in MHz
Characteristic	Mask Set 1L44X	Mask Set 1M88B
Core clock frequency (CLOCK)	200	266
External output clock frequency (CLKO)	50	67
Memory clock frequency (CK, CK)	100	133
TDM clock frequency (TxRCK, TxTCK)	50	67

Table 8. Clock Frequencies in MHz

Characteristic	Sumbal	Min	Max		
Characteristic	Symbol	IVIIII	Mask Set 1L44X	Mask Set 1M88B	
CLKIN frequency	F _{CLKIN}	10	100	100	
CLOCK frequency	F _{CORE}	_	200	266	
CK, CK frequency	F _{CK}	_	100	133	
TDMxRCK, TDMxTCK frequency	F _{TDMCK}	_	50	50	
CLKO frequency	F _{CKO}	_	50	67	
AHB/IPBus/APB clock frequency	F _{BCK}	_	100	133	
Note: The rise and fall time of external clocks should be					

Table 9. System Clock Parameters

Characteristic	Min	Max	Unit
CLKIN frequency	10	100	MHz
CLKIN slope	_	5	ns
CLKIN frequency jitter (peak-to-peak)	_	1000	ps
CLKO frequency jitter (peak-to-peak)	_	150	ps

2.5.2 Configuring Clock Frequencies

This section describes important requirements for configuring clock frequencies in the MSC7110 device when using the PLL block. To configure the device clocking, you must program four fields in the Clock Control Register (CLKCTL):

- PLLDVF field. Specifies the PLL division factor. The output of the divider block is the input to the multiplier block.
- PLLMLTF field. Specifies the PLL multiplication factor. The output from the multiplier block is the VCO.
- RNG field. Selects the available PLL frequency range.
- CKSEL field. Selects the source for the core clock.

There are restrictions on the frequency range permitted at the beginning of the multiplication portion of the PLL that affect the allowable values for the PLLDVF and PLLMLTF fields. The following sections define these restrictions and provide guidelines to configure the device clocking when using the PLL. Refer to the Clock and Power Management chapter in the *MSC711x Reference Manual* for details on the clock programming model.

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2.5.2.1 PLL Multiplier Restrictions

There are two restrictions for correct usage of the PLL block:

- The input frequency to the PLL multiplier block (that is, the output of the divider) must be in the range 10.5–19.5 MHz.
- The output frequency of the PLL multiplier must be in the range 300-600 MHz.

When programming the PLL for a desired output frequency using the PLLDVF, PLLMLTF, and RNG fields, you must meet these constraints.

2.5.2.2 Division Factors and Corresponding CLKIN Frequency Range

The value of the PLLDVF field determines the allowable CLKIN frequency range, as shown in Table 10.

Table 10. CLKIN Frequency Ranges by Divide Factor Value

PLLDVF Field Value	CI KIN Frequency Range		Comments				
0x00	1	10.5 to 19.5 MHz	Pre-Division by 1				
0x01	2	21 to 39 MHz	Pre-Division by 2				
0x02	3	31.5 to 58.5 MHz	Pre-Division by 3				
0x03	4	42 to 78 MHz	Pre-Division by 4				
0x04	5	52.5 to 97.5 MHz	Pre-Division by 5				
0x05	6	63 to 100 MHz	Pre-Division by 6				
0x06	7	73.5 to 100 MHz	Pre-Division by 7				
0x07	8	84 to 100 MHz	Pre-Division by 8				
0x08	9	94.5 to 100 MHz	Pre-Division by 9				
Note: The ma	Note: The maximum CLKIN frequency is 100 MHz. Therefore, the PLLDVF value must be in the range from 1–9.						

2.5.2.3 Multiplication Factor Range

The multiplier block output frequency ranges depend on the input clock frequency as shown in Table 11.

Table 11. PLLMLTF Ranges

Multiplier Block (Loop) Output Range		Minimum PLLMLTF Value	Maximum PLLMLTF Value		
	300 ≤ [Pre-Divided Clock × (PLLMLTF + 1)] ≤ 600 MHz	300/Pre-Divided Clock	600/Pre-Divided Clock		
Note: This table results from the allowed range for F _{Loop} . The minimum and maximum multiplication factors are dependent on the frequency of the Pre-Divided Clock.					

2.5.2.4 Allowed Core Clock Frequency Range

The frequency delivered to the core, extended core, and peripheral depends on the value of the CLKCTRL[RNG] bit as shown in **Table 12**.

Table 12. F_{vco} Frequency Ranges

CLI	KCTRL[RNG] Value	Allowed Range of F _{vco}		
	1	300 ≤ F _{vco} ≤ 600 MHz		
	0	150 ≤ F _{vco} ≤ 300 MHz		
Note:	: This table results from the allowed range for F _{vco} , which is F _{Loop} modified by CLKCTRL[RNG].			

This bit along with the CKSEL determines the frequency range of the core clock.

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Table 13. Resulting Ranges Permitted for the Core Clock

CLKC	TRL[CKSEL]	CLKCTRL[RNG]	Resulting Division Factor	Allowed Range of Core Clock	Comments		
	11	1	1	Reserved	Reserved		
	11	0	2	150 ≤ Core_Clk ≤ 200 MHz	Limited by range of PLL		
	01	1	2	150 ≤ Core_Clk ≤ 200 MHz	Limited by range of PLL		
	01	0	4	75 ≤ Core_Clk ≤ 150 MHz	Limited by range of PLL		
Note:	Note: This table results from the allowed range for F _{OUT} , which depends on clock selected via CLKCTRL[CKSEL].						

2.5.2.5 Core Clock Frequency Range When Using DDR Memory

The core clock can also be limited by the frequency range of the DDR devices in the system. **Table 14** summarizes this restriction.

Table 14. Core Clock Ranges When Using DDR

DDR Type	Allowed Frequency Range for DDR CK	Corresponding Range for the Core Clock	Comments
DDR 200 (PC-1600)	83–100 MHz	166 ≤ core clock ≤ 200 MHz	Core limited to 2 × maximum DDR frequency
DDR 266 (PC-2100)	83–133 MHz	166 ≤ core clock ≤ 266 MHz	Core limited to 2 × maximum DDR frequency
DDR 333 (PC-2600)	83–150 MHz	166 ≤ core clock ≤ 300 MHz	Core limited to 2 × maximum DDR frequency

2.5.3 Reset Timing

The MSC7110 device has several inputs to the reset logic. All MSC7110 reset sources are fed into the reset controller, which takes different actions depending on the source of the reset. The reset status register indicates the most recent sources to cause a reset. **Table 15** describes the reset sources.

Table 15. Reset Sources

Name	Direction	Description
Power-on reset (PORESET)	Input	Initiates the power-on reset flow that resets the MSC7110 and configures various attributes of the MSC7110. On PORESET, the entire MSC7110 device is reset. SPLL and DLL states are reset, HRESET is driven, the SC1400 extended core is reset, and system configuration is sampled. The system is configured only when PORESET is asserted.
External Hard reset (HRESET)	Input/ Output	Initiates the hard reset flow that configures various attributes of the MSC7110. While HRESET is asserted, HRESET is an open-drain output. Upon hard reset, HRESET is driven and the SC1400 extended core is reset.
Software watchdog reset	Internal	When the MSC7110 watchdog count reaches zero, a software watchdog reset is signalled. The enabled software watchdog event then generates an internal hard reset sequence.
Bus monitor reset	Internal	When the MSC7110 bus monitor count reaches zero, a bus monitor hard reset is asserted. The enabled bus monitor event then generates an internal hard reset sequence.
JTAG EXTEST, CLAMP, or HIGHZ command	Internal	When a Test Access Port (TAP) executes an EXTEST, CLAMP, or HIGHZ command, the TAP logic asserts an internal reset signal that generates an internal soft reset sequence.

Table 16 summarizes the reset actions that occur as a result of the different reset sources.

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Table 16. Reset Actions for Each Reset Source

	Power-On Reset (PORESET)	H <u>ard Rese</u> t (HRESET)	S <u>oft Rese</u> t (SRESET)
Reset Action/Reset Source	External only	External or Internal (Software Watchdog or Bus Monitor)	JTAG Command: EXTEST, CLAMP, or HIGHZ
Configuration pins sampled (refer to Section 2.5.3.1 for details).	Yes	No	No
PLL and clock synthesis states Reset	Yes	No	No
HRESET Driven	Yes	Yes	No
Software watchdog and bus time-out monitor registers	Yes	Yes	Yes
Clock synthesis modules (STOPCTRL, HLTREQ, and HLTACK) reset	Yes	Yes	Yes
Extended core reset	Yes	Yes	Yes
Peripheral modules reset	Yes	Yes	Yes

2.5.3.1 Power-On Reset (PORESET) Pin

Asserting $\overline{\text{PORESET}}$ initiates the power-on reset flow. $\overline{\text{PORESET}}$ must be asserted externally for at least 16 CLKIN cycles after external power to the MSC7110 reaches at least 2/3 V_{DD} .

2.5.3.2 Reset Configuration

The MSC7110 has two mechanisms for writing the reset configuration:

- From a host through the host interface (HDI16)
- From memory through the I²C interface

Five signal levels (see **Chapter 1** for signal description details) are sampled on PORESET deassertion to define the boot and operating conditions:

- BM[0-1]
- SWTE
- H8BIT
- HDSP

2.5.3.3 Reset Timing Tables

Table 17 and Figure 4 describe the reset timing for a reset configuration write.

Table 17. Timing for a Reset Configuration Write

No.	Characteristics	Expression	Unit
1	Required external PORESET duration minimum	16/F _{CLKIN}	clocks
2	Delay from PORESET deassertion to HRESET deassertion	521/F _{CLKIN}	clocks
Note:	Fimings are not tested, but are guaranteed by design.		

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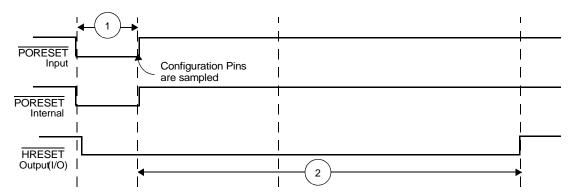


Figure 4. Timing Diagram for a Reset Configuration Write

2.5.4 DDR DRAM Controller Timing

This section provides the AC electrical characteristics for the DDR DRAM interface.

2.5.4.1 DDR DRAM Input AC Timing Specifications

Table 18 provides the input AC timing specifications for the DDR DRAM interface.

Table 18. DDR DRAM Input AC Timing

				М		
No.	Parameter	Symbol	Min	Mask Set 1L44X	Mask Set 1M88B	Unit
_	AC input low voltage	V _{IL}	_	V _{REF} – 0.31	V _{REF} – 0.31	V
_	AC input high voltage	V _{IH}	V _{REF} + 0.31	V _{DDM} + 0.3	V _{DDM} + 0.3	V
201	Maximum Dn input setup skew relative to DQSn input	_	_	1026	900	ps
202	Maximum Dn input hold skew relative to DQSn input	_	_	386	900	ps

Notes: 1. Maximum possible skew between a data strobe (DQSn) and any corresponding bit of data (D[8n + $\{0...7\}$] if $0 \le n \le 7$).

2. See Table 19 for t_{CK} value.

3. Dn should be driven at the same time as DQSn. This is necessary because the DQSn centering on the DQn data tenure is done internally.

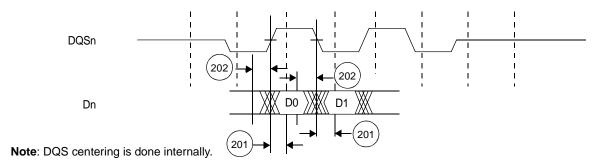


Figure 5. DDR DRAM Input Timing Diagram

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2.5.4.2 DDR DRAM Output AC Timing Specifications

Table 19 and Table 20 list the output AC timing specifications and measurement conditions for the DDR DRAM interface.

Table 19. DDR DRAM Output AC Timing

			М			
No.	Parameter	Symbol	Mask Set 1L44X	Mask Set 1M88B	Max	Unit
200	CK cycle time, (CK/CK crossing) ¹ • 100 MHz (DDR200) • 133 MHz (DDR266)	t _{CK}	10 Not applicable	1.0 7.52	_ _ _	ns ns
204	An/RAS/CAS/WE/CKE output setup with respect to CK	t _{DDKHAS}	0.5 × t _{CK} – 2250	0.5 × t _{CK} – 1000	_	ps
205	An/RAS/CAS/WE/CKE output hold with respect to CK	t _{DDKHAX}	$0.5 \times t_{CK} - 1250$	0.5 × t _{CK} - 1000	_	ps
206	CSn output setup with respect to CK	t _{DDKHCS}	$0.5 \times t_{CK} - 2250$	0.5 × t _{CK} - 1000	_	ps
207	CSn output hold with respect to CK	t _{DDKHCX}	$0.5 \times t_{CK} - 1250$	0.5 × t _{CK} - 1000	_	ps
208	CK to DQSn ²	t _{DDKHMH}	-600	-600	600	ps
209	Dn/DQMn output setup with respect to DQSn ³	^t DDKHDS, ^t DDKLDS	0.25 × t _{MCK} – 1050	$0.25 \times t_{CK} - 750$	_	ps
210	Dn/DQMn output hold with respect to DQSn ³	t _{DDKHDX,} t _{DDKLDX}	$0.25 \times t_{CK} - 1050$	$0.25 \times t_{CK} - 750$	_	ps
211	DQSn preamble start ⁴	t _{DDKHMP}	-0.25 × t _{CK}	-0.25 × t _{CK}	_	ps
212	DQSn epilogue end ⁵	t _{DDKHME}	-600	-600	600	ps

Notes:

- 1. All CK/CK referenced measurements are made from the crossing of the two signals ±0.1 V.
- 2. t_{DDKHMH} can be modified through the TCFG2[WRDD] DQSS override bits. The DRAM requires that the first write data strobe arrives 75–125% of a DRAM cycle after the write command is issued. Any skew between DQSn and CK must be considered when trying to achieve this 75%–125% goal. The TCFG2[WRDD] bits can be used to shift DQSn by 1/4 DRAM cycle increments. The skew in this case refers to an internal skew existing at the signal connections. By default, the CK/CK crossing occurs in the middle of the control signal (An/RAS/CAS/WE/CKE) tenure. Setting TCFG2[ACSM] bit shifts the control signal assertion 1/2 DRAM cycle earlier than the default timing. This means that the signal is asserted no earlier than 410 ps before the CK/CK crossing and no later than 677 ps after the crossing time; the device uses 1087 ps of the skew budget (the interval from –410 to +677 ps). Timing is verified by referencing the falling edge of CK. See Chapter 10 of the MSC711x Reference Manual for details.
- 3. Determined by maximum possible skew between a data strobe (DQS) and any corresponding bit of data. The data strobe should be centered inside of the data eye.
- 4. Please note that this spec is in reference to the DQSn first rising edge. It could also be referenced from CK(r), but due to programmable delay of the write strobes (TCFG2[WRDD]), there pre-amble may be extended for a full DRAM cycle. For this reason, we reference from DQSn.
- 5. All outputs are referenced to the rising edge of CK. Note that this is essentially the CK/DQSn skew in spec 208. In addition there is no real "maximum" time for the epilogue end. JEDEC does not require this is as a device limitation, but simply for the chip to guarantee fast enough write to read turn-around times. This is already guaranteed by the memory controller operation.

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Figure 6 shows the DDR DRAM output timing diagram.

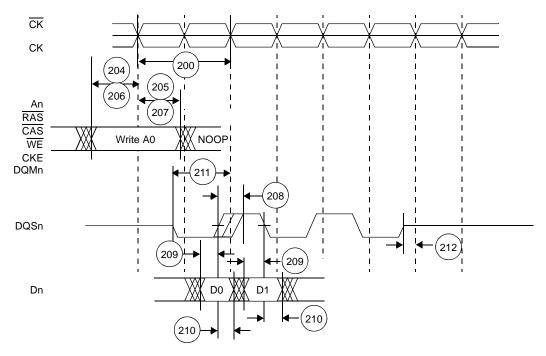


Figure 6. DDR DRAM Output Timing Diagram

Figure 7 provides the AC test load for the DDR DRAM bus.

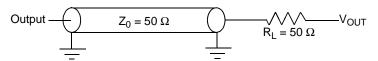


Figure 7. DDR DRAM AC Test Load

Table 20. DDR DRAM Measurement Conditions

	Symbol	DDR DRAM	Unit
V _{TH} ¹		V _{REF} ± 0.31 V	V
V _{OUT} ²		$0.5 \times V_{DDM}$	V
	Data input threshold measurement point. Data output measurement point.		

2.5.5 TDM Timing

Table 21. TDM Timing

No.	Characteristic	Expression	Min	Max	Units
300	TDMxRCK/TDMxTCK	TC	20.0	_	ns
301	TDMxRCK/TDMxTCK High Pulse Width	0.4 × TC	8.0	_	ns
302	TDMxRCK/TDMxTCK Low Pulse Width	0.4 × TC	8.0	_	ns
303	TDM all input Setup time		3.0	_	ns
304	TDMxRD Hold time		3.5	_	ns
305	TDMxTFS/TDMxRFS input Hold time		2.0	_	ns
306	TDMxTCK High to TDMxTD output active		4.0		ns

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Specifications

Table 21. TDM Timing

No.	Characteristic	Expression	Min	Max	Units
307	TDMxTCK High to TDMxTD output valid			14.0	ns
308	TDMxTD hold time		2.0	_	ns
309	TDMxTCK High to TDMxTD output high impedance		_	10.0	ns
310	TDMXTFS/TDMxRFS output valid		_	13.5	ns
311	TDMxTFS/TDMxRFS output hold time		2.5	_	ns

Notes: 1. Output values are based on 30 pF capacitive load.

Inputs are referenced to the sampling that the TDM is programmed to use. Outputs are referenced to the programming edge they are programmed to use. Use of the rising edge or falling edge as a reference is programmable. Refer to the MSC711x Reference Manual for details. TDMxTCK and TDMxRCK are shown using the rising edge.

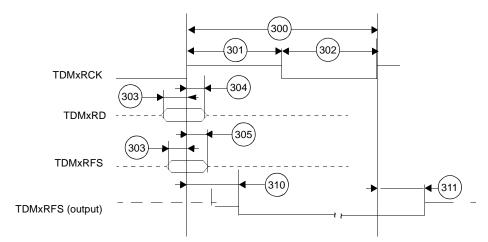


Figure 8. TDM Receive Signals

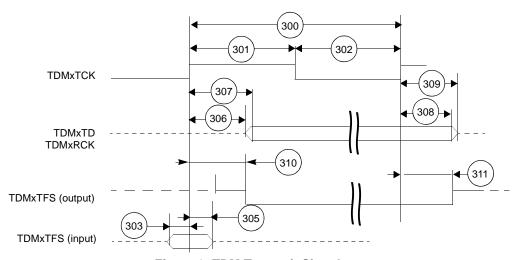


Figure 9. TDM Transmit Signals

2.5.6 HDI16 Signals

Table 22. Host Interface (HDI16) Timing^{1, 2}

No.	Characteristics ³	Mask Set 1L44X		Mask Set 1M88B		Unit
140.	Gharacter istics	Expression	Value	Expression	Value	
40	Host Interface Clock period	T _{HCLK}	Note 1	T _{CORE}	Note 1	ns

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Table 22. Host Interface (HDI16) Timing^{1, 2} (continued)

Na	Characteristics ³	Mask Set 1L	Mask Set 1L44X		88B	Unit
No.	Characteristics ³	Expression	Value	Expression	Value	
	Read data strobe minimum assertion width ⁴ HACK read minimum assertion width	3.0 × T _{HCLK}	Note 11	2.0 × T _{CORE} + 9.0	Note 11	ns
	Read data strobe minimum deassertion width ⁴ HACK read minimum deassertion width	1.5 × T _{HCLK}	Note 11	1.5 × T _{CORE}	Note 11	ns
	Read data strobe minimum deassertion width ⁴ after "Last Data Register" reads ^{5,6} , or between two consecutive CVR, ICR, or ISR reads ⁷ HACK minimum deassertion width after "Last Data Register" reads ^{5,6}	2.5 × T _{HCLK}	Note 11	2.5 × T _{CORE}	Note 11	ns
	Write data strobe minimum assertion width ⁸ HACK write minimum assertion width	1.5 × T _{HCLK}	Note 11	1.5 × T _{CORE}	Note 11	ns
	Write data strobe minimum deassertion width ⁸ HACK write minimum deassertion width after ICR, CVR and Data Register writes ⁵	2.5 × T _{HCLK}	Note 11	2.5 × T _{CORE}	Note 11	ns
	Host data input minimum setup time before write data strobe deassertion ⁸ Host data input minimum setup time before HACK write deassertion	_	3.0		2.5	ns
	Host data input minimum hold time after write data strobe deassertion ⁸ Host data input minimum hold time after HACK write deassertion	_	4.0	_	2.5	ns
	Read data strobe minimum assertion to output data active from high impedance ⁴ HACK read minimum assertion to output data active from high impedance	_	1.0	_	1.0	ns
	Read data strobe maximum assertion to output data valid ⁴ HACK read maximum assertion to output data valid	(2.0 × T _{HCLK}) + 8.0	Note 11	(2.0 × T _{CORE}) + 8.0	Note 11	ns
	Read data strobe maximum deassertion to output data high impedance ⁴ HACK read maximum deassertion to output data high impedance	_	8.0		9.0	ns
52	Output data minimum hold time after read data strobe deassertion Output data minimum hold time after HACK read deassertion	_	1.0		1.0	ns
	HCS[1-2] minimum assertion to read data strobe assertion ⁴	_	0.0	_	0.5	ns
54	HCS[1-2] minimum assertion to write data strobe assertion ⁸	_	0.0	_	0.0	ns
	HCS[1-2] maximum assertion to output data valid	$(2.0 \times T_{HCLK}) + 8.0$	Note 11	$(2.0 \times T_{CORE}) + 6.0$	Note 11	ns
	HCS[1-2] minimum hold time after data strobe deassertion ⁹	_	0.0	_	0.5	ns
57	HA[0-3], HRW minimum setup time before data strobe assertion ⁹	_	5.0	_	5.0	ns
58	HA[0-3], HRW minimum hold time after data strobe deassertion ⁹	_	5.0	_	5.0	ns
	Maximum delay from read data strobe deassertion to host request deassertion for "Last Data Register" read ^{4, 5, 10}	$(3.0 \times T_{HCLK}) + 8.0$	Note 11	$(3.0 \times T_{CORE}) + 6.0$	Note 11	ns
	Maximum delay from write data strobe deassertion to host request deassertion for "Last Data Register" write ^{5,8,10}	(3.0 × T _{HCLK}) + 8.0	Note 11	(3.0 × T _{CORE}) + 6.0	Note 11	ns
	Minimum delay from DMA HACK (OAD=0) or Read/Write data strobe(OAD=1) deassertion to HREQ assertion.	(2.0 × T _{HCLK}) + 1.0	Note 11	(2.0 × T _{CORE}) + 1.0	Note 11	ns
64	Maximum delay from DMA HACK (OAD=0) or Read/Write data strobe(OAD=1) assertion to HREQ deassertion	$(5.0 \times T_{HCLK}) + 8.0$	Note 11	$(5.0 \times T_{CORE}) + 6.0$	Note 11	ns

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Table 22. Host Interface (HDI16) Timing^{1, 2} (continued)

No.	Characteristics ³	Mask Set 1L44X		Mask Set 1M88B		Unit
NO.		Expression	Value	Expression	Value	

- $T_{HCLK} = 2/$ (Core Clock). At 200 MHz, $T_{HCLK} = 10$ ns. $T_{CORE} =$ core clock period. At 266 MHz, $T_{CORE} = 3.75$ ns. In the timing diagrams below, the controls pins are drawn as active low. The pin polarity is programmable. Notes:
 - 2.
 - V_{DD} = 3.3 V ± 0.15 V; T_J = -40°C to +105 °C, C_L = 30 pF for maximum delay timings and C_L = 0 pF for minimum delay timings.
 - The read data strobe is HRD/HRD in the dual data strobe mode and HDS/HDS in the single data strobe mode. 4.
 - 5. For 64-bit transfers, The "last data register" is the register at address 0x7, which is the last location to be read or written in data transfers. This is RX0/TX0 in the little endian mode (HBE = 0), or RX3/TX3 in the big endian mode (HBE = 1).
 - This timing is applicable only if a read from the "last data register" is followed by a read from the RXL, RXM, or RXH registers 6. without first polling RXDF or HREQ bits, or waiting for the assertion of the HREQ/HREQ signal.
 - 7. This timing is applicable only if two consecutive reads from one of these registers are executed.
 - The write data strobe is HWR in the dual data strobe mode and HDS in the single data strobe mode.
 - The data strobe is host read (HRD/HRD) or host write (HWR/HWR) in the dual data strobe mode and host data strobe (HDS/HDS) in the single data strobe mode.
 - 10. The host request is $\overline{\text{HREQ}}/\text{HREQ}$ in the single host request mode and $\overline{\text{HRRQ}}/\text{HRRQ}$ and $\overline{\text{HTRQ}}/\text{HTRQ}$ in the double host request mode. HRRQ/HRRQ is deasserted only when HOTX fifo is empty, HTRQ/HTRQ is deasserted only if HORX fifo is full (treat as level Host Request).
 - Compute the value using the expression.
 - 12. For mask set 1M88B, the read and write data strobe minimum deassertion width for non-"last data register" accesses in single and dual data strobe modes is based on timings 57 and 58.

Figure 10 and Figure 11 show HDI16 read signal timing. Figure 12 and Figure 13 show HDI16 write signal timing.

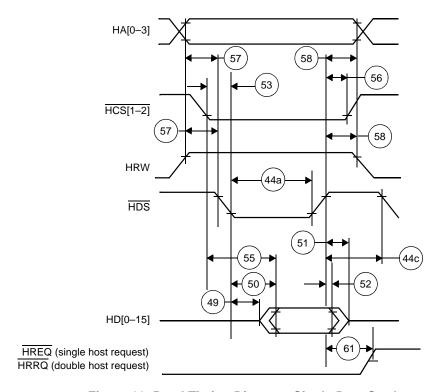


Figure 10. Read Timing Diagram, Single Data Strobe

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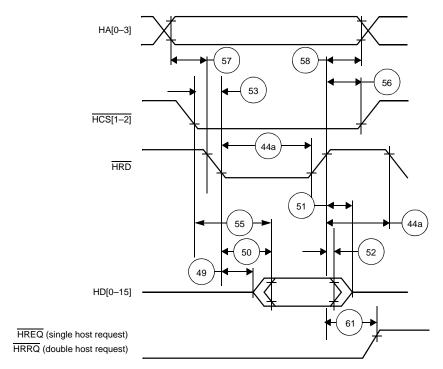


Figure 11. Read Timing Diagram, Double Data Strobe

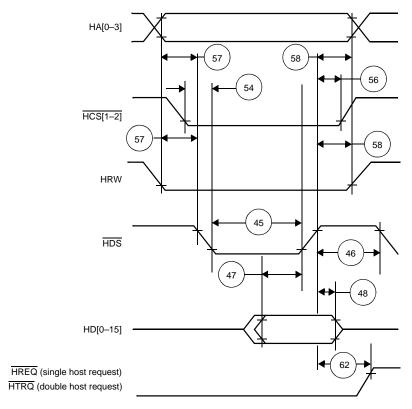


Figure 12. Write Timing Diagram, Single Data Strobe

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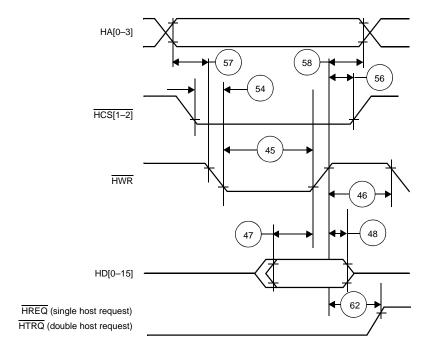


Figure 13. Write Timing Diagram, Double Data Strobe

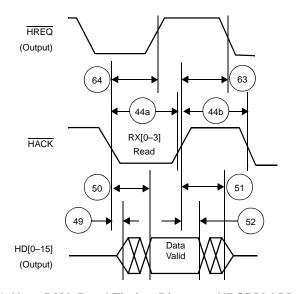


Figure 14. Host DMA Read Timing Diagram, HPCR[OAD] = 0

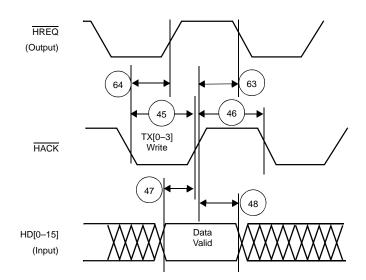


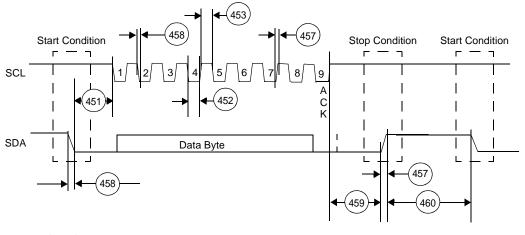
Figure 15. Host DMA Write Timing Diagram, HPCR[OAD] = 0



I²C Timing 2.5.7

Table 23. I²C Timing

No.	Characteristic	Fast	1114	
		Min	Max	Unit
450	SCL clock frequency	0	400	kHz
451	Hold time START condition	(Clock period/2) – 0.3	_	μs
452	SCL low period	(Clock period/2) – 0.3	_	μs
453	SCL high period	(Clock period/2) – 0.1	_	μs
454	Repeated START set-up time (not shown in figure)	2 × 1/F _{BCK}	_	μs
455	Data hold time	0	_	μs
456	Data set-up time	250	_	ns
457	SDA and SCL rise time	_	700	ns
458	SDA and SCL fall time	_	300	ns
459	Set-up time for STOP	(Clock period/2) – 0.7	_	μs
460	Bus free time between STOP and START	(Clock period/2) – 0.3	_	μs
Note:	SDA set-up time is referenced to the rising edge of SCL. SDA hold time is referenced to the falling edge of SCL. Load capacitance on SDA and SCL is 400 pF.			



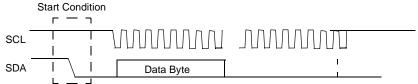


Figure 16. I²C Timing Diagram

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2.5.8 UART Timing

Table 24. UART Timing

No.	Characteristics	Expression	Mask Set 1L44X		Mask Set 1M88B		Unit
			Min	Max	Min	Max	
_	Internal bus clock (APBCLK)	F _{CORE} /2	_	100	_	133	MHz
_	Internal bus clock period (1/APBCLK)	T _{APBCLK}	10.0	_	7.52	_	ns
400	URXD and UTXD inputs high/low duration	16 × T _{APBCLK}	160.0		120.3		ns
401	URXD and UTXD inputs rise/fall time		_	5	_	5	ns
402	UTXD output rise/fall time		_	5	_	5	ns

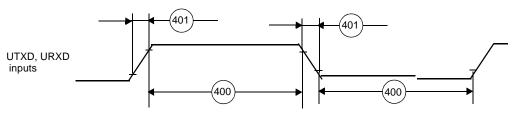


Figure 17. UART Input Timing

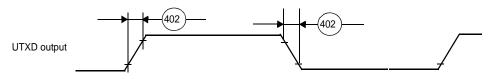


Figure 18. UART Output Timing

2.5.9 EE Timing

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Table 25. EE0 Timing

Number	Characteristics	Туре	Min	
65	EE0 input to the core	Asynchronous	4 core clock periods	
66	EE0 output from the core	Synchronous to core clock	1 core clock period	

- **Notes:** 1. The core clock is the SC1400 core clock. The ratio between the core clock and CLKOUT is configured during power-on-reset.
 - 2. Configure the direction of the EE pin in the EE_CTRL register (see the SC1400 Core Reference Manual for details.
 - Refer to **Table 15** for details on EE pin functionality.

Figure 19 shows the signal behavior of the EE pin.

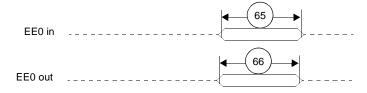


Figure 19. EE Pin Timing

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2.5.10 Event Timing

Table 26. EVNT Signal Timing

Number	Characteristics	Туре	Min	
67	EVNT as input	Asynchronous	1.5 × APBCLK periods	
68	EVNT as output	Synchronous to core clock	1 APBCLK period	
Notes: 1. Refer to Table 24 for a definition of the APBCLK period.				
Direction of the EVNT signal is configured through the GPIO and Event port registers.				
3. R	3. Refer to the MSC711x Reference Manual for details on EVNT pin functionality.			

Figure 20 shows the signal behavior of the EVNT pin.

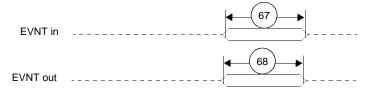


Figure 20. EVNT Pin Timing

2.5.11 GPIO Timing

Table 27. GPIO Signal Timing^{1,2,3}

Number	Characteristics	Туре	Min
601	GPI ^{4.5}	Asynchronous	1.5 × APBCLK periods
602	GPO ⁵	Synchronous to core clock	1 APBCLK period
603	Port A edge-sensitive interrupt	Asynchronous	1.5 × APBCLK periods
604	Port A level-sensitive interrupt	Asynchronous	3 × APBCLK periods ⁶

- Notes: 1. Refer to Table 24 for a definition of the APBCLK period.
 - 2. Direction of the GPIO signal is configured through the GPIO port registers.
 - 3. Refer to MSC711x Reference Manual for details on GPIO pin functionality.
 - 4. GPI data is synchronized to the APBCLK internally and the minimum listed is the capability of the hardware to capture data into a register when the GPA_DR is read. The specification is not tested due to the asynchronous nature of the input and dependence on the state of the DSP core. It is guaranteed by design.
 - 5. The input and output signals cannot toggle faster than 50 MHz.
 - 6. Level-sensitive interrupts should be held low until the system determines (via the service routine) that the interrupt is acknowledged.

Figure 21 shows the signal behavior of the GPI/GPO pin.

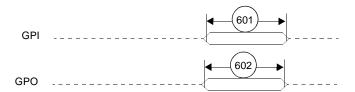


Figure 21. GPI/GPO Pin Timing

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2.5.12 JTAG Signals

Table 28. JTAG Timing

No.	Characteristics	All freq	All frequencies		
	Characteristics	Min Max			
700	TCK frequency of operation (1/(T _C × 3); maximum 22 MHz)	0.0	40.0	MHz	
701	TCK cycle time	25.0	_	ns	
702	TCK clock pulse width measured at V _{M =} 1.6 V	11.0	_	ns	
703	TCK rise and fall times	0.0	3.0	ns	
704	Boundary scan input data set-up time	5.0	_	ns	
705	Boundary scan input data hold time	14.0	_	ns	
706	TCK low to output data valid	0.0	20.0	ns	
707	TCK low to output high impedance	0.0	20.0	ns	
708	TMS, TDI data set-up time	5.0	_	ns	
709	TMS, TDI data hold time	25.0	_	ns	
710	TCK low to TDO data valid	0.0	24.0	ns	
711	TCK low to TDO high impedance	0.0	10.0	ns	
712	TRST assert time	100.0	_	ns	
Note:	All timings apply to OCE module data transfers as the OCE module uses the JTAG port as an interface.				

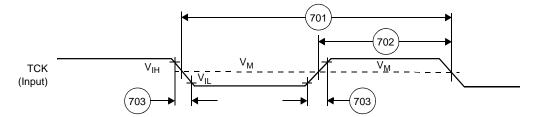


Figure 22. Test Clock Input Timing Diagram



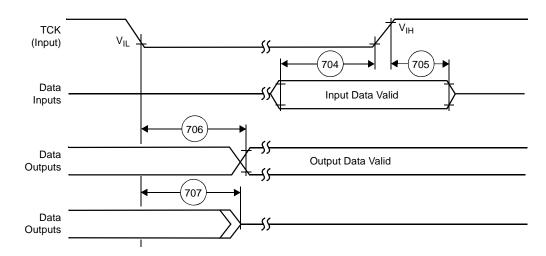


Figure 23. Boundary Scan (JTAG) Timing Diagram

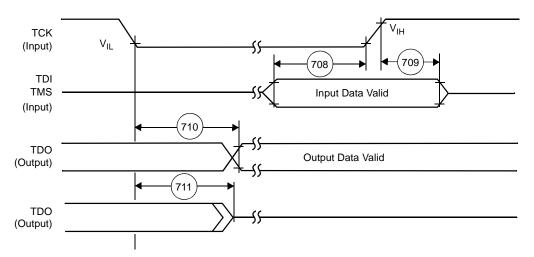


Figure 24. Test Access Port Timing Diagram



Figure 25. TRST Timing Diagram

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ware Design Considerations

Hardware Design Considerations 3

This section described various areas to consider when incorporating the MSC7110 device into a system design.

3.1 Thermal Design Considerations

An estimation of the chip-junction temperature, T_I, in °C can be obtained from the following:

$$T_J = T_A + (R_{\mathbf{\Omega}JA} \times P_D)$$
 Eqn. 1

where

 T_A = ambient temperature near the package (°C)

 $R_{OJA} = junction-to-ambient thermal resistance (°C/W)$

 $P_D = P_{INT} + P_{I/O} = power dissipation in the package (W)$

 $P_{INT} = I_{DD} \times V_{DD} = internal power dissipation (W)$

 $P_{I/O}$ = power dissipated from device on output pins (W)

The power dissipation values for the MSC7110 are listed in **Table 4**. The ambient temperature for the device is the air temperature in the immediate vicinity that would cool the device. The junction-to-ambient thermal resistances are JEDEC standard values that provide a quick and easy estimation of thermal performance. There are two values in common usage: the value determined on a single layer board and the value obtained on a board with two planes. The value that more closely approximates a specific application depends on the power dissipated by other components on the printed circuit board (PCB). The value obtained using a single layer board is appropriate for tightly packed PCB configurations. The value obtained using a board with internal planes is more appropriate for boards with low power dissipation (less than 0.02 W/cm² with natural convection) and well separated components. Based on an estimation of junction temperature using this technique, determine whether a more detailed thermal analysis is required. Standard thermal management techniques can be used to maintain the device thermal junction temperature below its maximum. If T_I appears to be too high, either lower the ambient temperature or the power dissipation of the chip.

You can verify the junction temperature by measuring the case temperature using a small diameter thermocouple (40 gauge is recommended) or an infrared temperature sensor on a spot on the device case. Use the following equation to determine T₁:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$
 Eqn. 2

where

 T_T = thermocouple (or infrared) temperature on top of the package (°C)

 Ψ_{IT} = thermal characterization parameter (°C/W)

 P_D = power dissipation in the package (W)



3.2 Power Supply Design Considerations

This section outlines the MSC7110 power considerations: power supply, power sequencing, power planes, decoupling, power supply filtering, and power consumption. It also presents a recommended power supply design and options for low-power consumption. For information on AC/DC electrical specifications and thermal characteristics, refer to **Section 2**.

3.2.1 Power Supply

The MSC7110 requires four input voltages, as shown in **Table 29**.

Table 29. MSC7110 Voltages

Voltage	Symbol	Value
Core	V _{DDC}	1.2 V
Memory	V_{DDM}	2.5 V
Reference	V _{REF}	1.25 V
I/O	V _{DDIO}	3.3 V

You should supply the MSC7110 core voltage via a variable switching supply or regulator to allow for compatibility with possible core voltage changes on future silicon revisions. The core voltage is supplied with 1.2 V (+5% and -10%) across V_{DDC} and GND and the I/O section is supplied with 3.3 V (± 10%) across V_{DDIO} and GND. The memory and reference voltages supply the DDR memory controller block. The memory voltage is supplied with 2.5 V across V_{DDM} and GND. The reference voltage is supplied across V_{REF} and GND and must be between $0.49 \times V_{DDM}$ and $0.51 \times V_{DDM}$. Refer to the JEDEC standard JESD8 (Stub Series Terminated Logic for 2.5 Volts (STTL_2)) for memory voltage supply requirements.

3.2.2 Power Sequencing

One consequence of multiple power supplies is that the voltage rails ramp up at different rates when power is initially applied. The rates depend on the power supply, the type of load on each power supply, and the way different voltages are derived. It is extremely important to observe the power up and power down sequences at the board level to avoid latch-up, forward biasing of ESD devices, and excessive currents, which all lead to severe device damage.

Note: There are five possible power-up/power-down sequence cases. The first four cases listed in the following sections are recommended for new designs. The fifth case is not recommended for new designs and must be carefully evaluated for current spike risks based on actual information for the specific application.

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ware Design Considerations

3.2.2.1 Case 1

The power-up sequence is as follows:

- 1. Turn on the V_{DDIO} (3.3 V) supply first.
- 2. Turn on the V_{DDC} (1.2 V) supply second.
- 3. Turn on the V_{DDM} (2.5 V) supply third.
- 4. Turn on the V_{REF} (1.25 V) supply fourth (last).

The power-down sequence is as follows:

- 1. Turn off the V_{REF} (1.25 V) supply first.
- 2. Turn off the V_{DDM} (2.5 V) supply second.
- 3. Turn off the V_{DDC} (1.2 V) supply third.
- 4. Turn of the V_{DDIO} (3.3 V) supply fourth (last).

Use the following guidelines:

- Make sure that the time interval between the ramp-down of V_{DDIO} and V_{DDC} is less than 10 ms.
- Make sure that the time interval between the ramp-up or ramp-down for V_{DDC} and V_{DDM} is less than 10 ms for power-up and power-down.
- Refer to **Figure 26** for relative timing for power sequencing case 1.

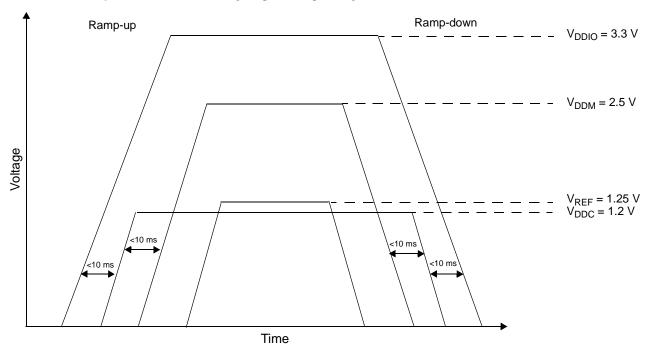


Figure 26. Voltage Sequencing Case 1



3.2.2.2 Case 2

The power-up sequence is as follows:

- 1. Turn on the V_{DDIO} (3.3 V) supply first.
- 2. Turn on the V_{DDC} (1.2 V) and V_{DDM} (2.5 V) supplies simultaneously (second).
- 3. Turn on the V_{REF} (1.25 V) supply last (third).

Note: Make sure that the time interval between the ramp-up of V_{DDIO} and V_{DDC}/V_{DDM} is less than 10 ms.

The power-down sequence is as follows:

- 1. Turn off the V_{REF} (1.25 V) supply first.
- 2. Turn off the V_{DDM} (2.5 V) supply second.
- 3. Turn off the V_{DDC} (1.2 V) supply third.
- 4. Turn of the V_{DDIO} (3.3 V) supply fourth (last).

Use the following guidelines:

- Make sure that the time interval between the ramp-down for V_{DDIO} and V_{DDC} is less than 10 ms.
- Make sure that the time interval between the ramp-up or ramp-down for V_{DDC} and V_{DDM} is less than 10 ms for power-up and power-down.
- Refer to **Figure 27** for relative timing for Case 2.

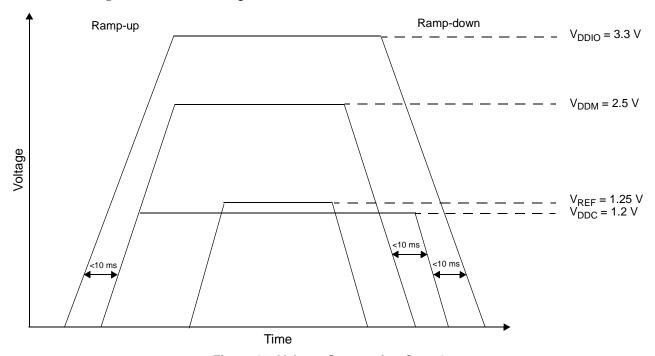


Figure 27. Voltage Sequencing Case 2

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3.2.2.3 Case 3

The power-up sequence is as follows:

- 1. Turn on the V_{DDIO} (3.3 V) supply first.
- 2. Turn on the V_{DDC} (1.2 V) supply second.
- 3. Turn on the V_{DDM} (2.5 V) and V_{REF} (1.25 V) supplies simultaneously (third).

Note: Make sure that the time interval between the ramp-up of V_{DDIO} and V_{DDC} is less than 10 ms.

The power-down sequence is as follows:

- 1. Turn off the V_{DDM} (2.5 V) and V_{REF} (1.25 V) supplies simultaneously (first).
- 2. Turn off the V_{DDC} (1.2 V) supply second.
- 3. Turn of the V_{DDIO} (3.3 V) supply third (last).

Use the following guidelines:

- $\bullet \quad \text{Make sure that the time interval between the ramp-down for V_{DDIO} and V_{DDC} is less than 10 ms.}\\$
- Make sure that the time interval between the ramp-up or ramp-down time for V_{DDC} and V_{DDM} is less than 10 ms for power-up and power-down.
- Refer to **Figure 28** for relative timing for Case 3.

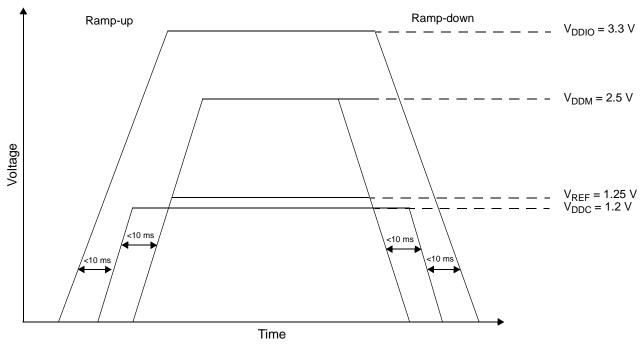


Figure 28. Voltage Sequencing Case 3

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3.2.2.4 Case 4

The power-up sequence is as follows:

- 1. Turn on the V_{DDIO} (3.3 V) supply first.
- 2. Turn on the V_{DDC} (1.2 V), V_{DDM} (2.5 V), and V_{REF} (1.25 V) supplies simultaneously (second).

Note: Make sure that the time interval between the ramp-up of V_{DDIO} and V_{DDC} is less than 10 ms.

The power-down sequence is as follows:

- 1. Turn off the V_{DDC} (1.2 V), V_{REF} (1.25 V), and V_{DDM} (2.5 V) supplies simultaneously (first).
- 2. Turn of the V_{DDIO} (3.3 V) supply last.

Use the following guidelines:

- Make sure that the time interval between the ramp-up or ramp-down time for V_{DDC} and V_{DDM} is less than 10 ms for power-up and power-down.
- Refer to **Figure 29** for relative timing for Case 4.

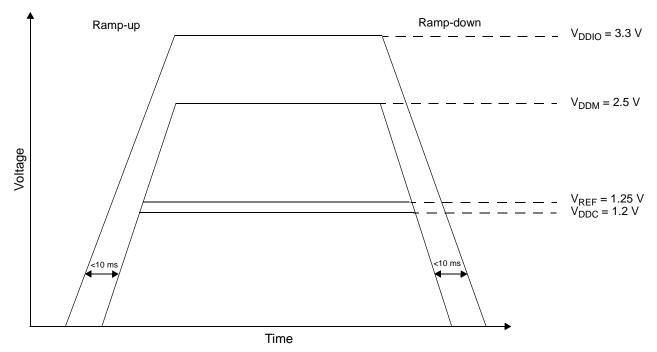


Figure 29. Voltage Sequencing Case 4

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3.2.2.5 Case 5 (not recommended for new designs)

The power-up sequence is as follows:

- 1. Turn on the V_{DDIO} (3.3 V) supply first.
- 2. Turn on the V_{DDM} (2.5 V) supply second.
- 3. Turn on the V_{DDC} (1.2 V) supply third.
- 4. Turn on the V_{REF} (1.25 V) supply fourth (last).

Note: Make sure that the time interval between the ramp-up of V_{DDIO} and V_{DDM} is less than 10 ms.

The power-down sequence is as follows:

- 1. Turn off the V_{REF} (1.25 V) supply first.
- 2. Turn off the V_{DDC} (1.2 V) supply second.
- 3. Turn off the V_{DDM} (2.5 V) supply third.
- 4. Turn of the V_{DDIO} (3.3 V) supply fourth (last).

Use the following guidelines:

- Make sure that the time interval between the ramp-down of V_{DDIO} and V_{DDM} is less than 10 ms.
- Make sure that the time interval between the ramp-up or ramp-down for V_{DDC} and V_{DDM} is less than 2 ms for power-up and power-down.
- Refer to **Figure 30** for relative timing for power sequencing case 5.

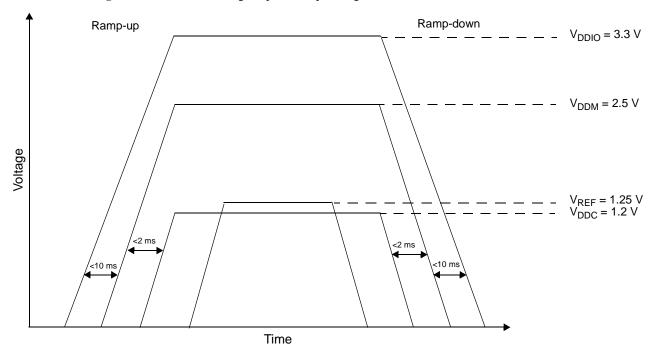


Figure 30. Voltage Sequencing Case 5

Note: Cases 1, 2, 3, and 4 are recommended for system design. Designs that use Case 5 may have large current spikes on the V_{DDM} supply at startup and is not recommended for most designs. If a design uses case 5, it must accommodate the potential current spikes. Verify risks related to current spikes using actual information for the specific application.



3.2.3 Power Planes

Each power supply pin (V_{DDC} , V_{DDM} , and V_{DDIO}) should have a low-impedance path to the board power supply. Each GND pin should be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on the device. The MSC7110 V_{DDC} power supply pins should be bypassed to ground using decoupling capacitors. The capacitor leads and associated printed circuit traces connecting to device power pins and GND should be kept to less than half an inch per capacitor lead. A minimum four-layer board that employs two inner layers as power and GND planes is recommended. See **Section 3.5** for DDR Controller power guidelines.

3.2.4 Decoupling

Both the I/O voltage and core voltage should be decoupled for switching noise. For I/O decoupling, use standard capacitor values of $0.01\,\mu\text{F}$ for every two to three voltage pins. For core voltage decoupling, use two levels of decoupling. The first level should consist of a $0.01\,\mu\text{F}$ high frequency capacitor with low effective series resistance (ESR) and effective series inductance (ESL) for every two to three voltage pins. The second decoupling level should consist of two bulk/tantalum decoupling capacitors, one $10\,\mu\text{F}$ and one $47\,\mu\text{F}$, (with low ESR and ESL) mounted as closely as possible to the MSC7110 voltage pins. Additionally, the maximum drop between the power supply and the DSP device should be $15\,\text{mV}$ at $1\,\text{A}$.

3.2.5 PLL Power Supply Filtering

The MSC7110 V_{DDPLL} power signal provides power to the clock generation PLL. To ensure stability of the internal clock, the power supplied to this pin should be filtered with capacitors that have low and high frequency filtering characteristics. V_{DDPLL} can be connected to V_{DDC} through a 2 Ω resistor. V_{SSPLL} can be tied directly to the GND plane. A circuit similar to the one shown in **Figure 31** is recommended. The PLL loop filter should be placed as closely as possible to the V_{DDPLL} pin (which are located on the outside edge of the silicon package) to minimize noise coupled from nearby circuits. The 0.01 μ F capacitor should be closest to V_{DDPLL} , followed by the 0.1 μ F capacitor, the 10 μ F capacitor, and finally the 2- Ω resistor to V_{DDC} . These traces should be kept short.

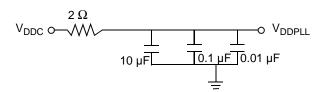


Figure 31. PLL Power Supply Filter Circuits

3.2.6 Power Consumption

You can reduce power consumption in your design by controlling the power consumption of the following regions of the device:

- Extended core. Use the SC1400 Stop and Wait modes by issuing a **stop** or **wait** instruction.
- Clock synthesis module. Disable the PLL, timer, watchdog, or DDR clocks or disable the CLKO pin.
- AHB subsystem. Freeze or shut down the AHB subsystem using the GPSCTL[XBR_HRQ] bit.
- Peripheral subsystem. Halt the individual on-device peripherals such as the DDR memory controller, HDI16, TDM, UART, I²C, and timer modules.

For details, see the "Clocks and Power Management" chapter of the MSC711x Reference Manual.

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3.2.7 Power Supply Design

One of the most common ways to derive power is to use either a simple fixed or adjustable linear regulator. For the system I/O voltage supply, a simple fixed 3.3 V supply can be used. However, a separate adjustable linear regulator supply for the core voltage V_{DDC} should be implemented. For the memory power supply, regulators are available that take care of all DDR power requirements.

Table 30. Recommended Power Supply Ratings

Supply	Symbol	Nominal Voltage	Current Rating
Core	V _{DDC}	1.2 V	1.5 A per device
Memory	V_{DDM}	2.5 V	0.5 A per device
Reference	V _{REF}	1.25 V	10 μA per device
I/O	V _{DDIO}	3.3 V	1.0 A per device

3.3 Estimated Power Usage Calculations

The following equations permit estimated power usage to be calculated for individual design conditions. Overall power is derived by totaling the power used by each of the major subsystems:

$$P_{TOTAL} = P_{CORE} + P_{PERIPHERALS} + P_{DDRIO} + P_{IO} + P_{LEAKAGE}$$
 Eqn. 3

This equation combines dynamic and static power. Dynamic power is determined using the generic equation:

$$C \times V^2 \times F \times 10^{-3} \text{ mW}$$
 Eqn. 4

where,

C = load capacitance in pF

V = peak-to-peak voltage swing in V

F = frequency in MHz

3.3.1 Core Power

Estimation of core power is straightforward. It uses the generic dynamic power equation and assumes that the core load capacitance is 750 pF, core voltage swing is 1.2 V, and the core frequency is 200 MHz or 266 MHz. This yields:

$$P_{CORE} = 750 \text{ pF} \times (1.2 \text{ V})^2 \times 200 \text{ MHz} \times 10^{-3} = 216 \text{ mW}$$
 Eqn. 5

$$P_{CORE} = 750 \text{ pF} \times (1.2 \text{ V})^2 \times 266 \text{ MHz} \times 10^{-3} = 287 \text{ mW}$$
 Eqn. 6

This equation allows for adjustments to voltage and frequency if necessary.

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3.3.2 Peripheral Power

Peripherals include the DDR memory controller, DMA controller, HDI16, TDM, UART, timers, GPIOs, and the I²C module. Basic power consumption by each module is assumed to be the same and is computed by using the following equation which assumes an effective load of 20 pF, core voltage swing of 1.2 V, and a switching frequency of 100 MH or 133 MHz. This yields:

$$P_{PERIPHERAI} = 20 \text{ pF} \times (1.2 \text{ V})^2 \times 100 \text{ MHz} \times 10^{-3} = 2.88 \text{ mW per peripheral}$$
 Eqn. 7

$$P_{PERIPHERAL} = 20 \ pF \times (1.2 \ V)^2 \times 133 \ MHz \times 10^{-3} = 3.83 \ mW \ per \ peripheral$$
 Eqn. 8

Multiply this value by the number of peripherals used in the application to compute the total peripheral power consumption.

3.3.3 External Memory Power

Estimation of power consumption by the DDR memory system is complex. It varies based on overall system signal line usage, termination and load levels, and switching rates. Because the DDR memory includes terminations external to the MSC7110 device, the 2.5 V power source provides the power for the termination, which is a static value of 16 mA per signal driven high. The dynamic power is computed, however, using a differential voltage swing of ± 0.200 V, yielding a peak-to-peak swing of 0.4 V. The equations for computing the DDR power are:

$$P_{DDRIO} = P_{STATIC} + P_{DYNAMIC}$$
 Eqn. 9

$$P_{STATIC} = (unused pins \times \% driven high) \times 16 \text{ mA} \times 2.5 \text{ V}$$
 Eqn. 10

$$P_{DYNAMIC} = (pin\ activity\ value) \times 20\ pF \times (0.4\ V)^2 \times 200\ MHz \times 10^{-3}\ mW$$
 Eqn. 11

$$P_{DYNAMIC} = (pin\ activity\ value) \times 20\ pF \times (0.4\ V)^2 \times 266\ MHz \times 10^{-3}\ mW$$
 Eqn. 12

pin activity value = (active data lines \times % activity \times % data switching) + (active address lines \times % activity) Eqn. 13

As an example, assume the following:

unused pins = 16 (DDR uses 16-pin mode)

% driven high = 50%

active data lines = 16

% activity = 60%

% data switching = 50%

active address lines = 3

In this example, the DDR memory power consumption is:

$$P_{DDRIO} = ((16 \times 0.5) \times 16 \times 2.5) + (((16 \times 0.6 \times 0.5) + (3 \times 0.6)) \times 20 \times (0.4)^{2} \times 200 \times 10^{-3}) = 324.2 \text{ mW}$$
 Eqn. 14

$$P_{DDRIO} = ((16 \times 0.5) \times 16 \times 2.5) + (((16 \times 0.6 \times 0.5) + (3 \times 0.6)) \times 20 \times (0.4)^{2} \times 266 \times 10^{-3}) = 326.3 \text{ mW}$$
 Eqn. 15

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3.3.4 External I/O Power

The estimation of the I/O power is similar to the computation of the peripheral power estimates. The power consumption per signal line is computed assuming a maximum load of 20 pF, a voltage swing of 3.3 V, and a switching frequency of 25 MHz or 33 MHz, which yields:

$$P_{IO} = 20 \ pF \times (3.3 \ V)^2 \times 25 \ MHz \times 10^{-3} = 5.44 \ mW \ per I/O \ line$$
 Eqn. 16

$$P_{IO} = 20 \text{ pF} \times (3.3 \text{ V})^2 \times 33 \text{ MHz} \times 10^{-3} = 7.19 \text{ mW per I/O line}$$
 Eqn. 17

Multiply this number by the number of I/O signal lines used in the application design to compute the total I/O power.

Note: The signal loading depends on the board routing. For systems using a single DDR device, the load could be as low as 7 pF.

3.3.5 Leakage Power

The leakage power is for all power supplies combined at a specific temperature. The value is temperature dependent. The observed leakage value at room temperature is 64 mW.

3.3.6 Example Total Power Consumption

Using the examples in this section and assuming four peripherals and 10 I/O lines active, a total power consumption value is estimated as the following:

$$P_{TOTAL}(200 \text{ MHz core}) = 216 + (4 \times 2.88) + 324.2 + (10 \times 5.44) + 64 = 670.12 \text{ mW}$$
 Eqn. 18

$$P_{TOTAL}(266 \text{ MHz core}) = 287 + (4 \times 3.83) + 326.3 + (10 \times 7.19) + 64 = 764.52 \text{ mW}$$
 Eqn. 19

3.4 Reset and Boot

This section describes the recommendations for configuring the MSC7110 at reset and boot.

3.4.1 Reset Circuit

HRESET is a bidirectional signal and, if driven as an input, should be driven with an open collector or open-drain device. For an open-drain output such as HRESET, take care when driving many buffers that implement input bus-hold circuitry. The bus-hold currents can cause enough voltage drop across the pull-up resistor to change the logic level to low. Either a smaller value of pull-up or less current loading from the bus-hold drivers overcomes this issue. To avoid exceeding the MSC7110 output current, the pull-up value should not be too small (a 1 KΩ pull-up resistor is used in the MSC711xADS reference design).

3.4.2 Reset Configuration Pins

Table 31 shows the MSC7110 reset configuration signals. These signals are sampled at the deassertion (rising edge) of PORESET. For details, refer to the Reset chapter of the *MSC711x Reference Manual*.

Table 31. Reset Configuration Signals

Signal	Description	Settings		
BM[1-0]	Determines boot mode.	0	Boot from HDI16 port.	
		01	Boot from I2C.	
		1x	Reserved.	
SWTE	Determines watchdog functionality.	0 Watchdog timer disabled.		
		1	Watchdog timer enabled.	
HDSP	Configures HDI16 strobe polarity.	0 Host Data strobes active low.		
		1	Host Data strobes active high.	
H8BIT	Configures HDI16 operation mode.	0	0 HDI16 port configured for 16-bit operation.	
		1	HDI16 port configured for 8-bit operation.	

3.4.3 Boot

After a power-on reset, the PLL is bypassed and the device is directly clocked from the CLKIN pin. Using this input clock, the system initializes using the boot loader program that resides in the internal ROM. After initialization, the DSP core can enable the PLL and start the device operating at a higher speed. The MSC7110 can boot from an external host through the HDI16 or download a user program through the I²C port. The boot operating mode is set by configuring the BM[1–0] signals sampled at the rising edge of PORESET, as shown in **Table 32**.

Table 32. Boot Mode Settings

BM1	BM0	Boot Source		
0	0	External host via HDI16 with the PLL disabled.		
0	1	I ² C.		
1	0	External host via the HDI16 with the PLL enabled.		
1	1	Reserved.		

3.4.3.1 HDI16 Boot

If the MSC7110 device boots from an external host through the HDI16, the port is configured as follows:

- Operate in Non-DMA mode.
- Operate in polled mode on the device side.
- Operate in polled mode on the external host side.
- External host must write four 16-bit values at a time with the first word as the most significant and the fourth word as the least significant.

When booting from a power-on reset, the HDI16 is additionally configurable as follows:

- 8- or 16-bit mode as specified by the H8BIT pin.
- Data strobe as specified by the HDSP and HDDS pins.

These pins are sampled only on the deassertion of power-on reset. During a boot from a hard reset, the configuration of these pins is unaffected.

Note: When the HDI16 is used for booting or other purposes, bit 0 is the least significant bit and not the most significant bit as for other DSP products.



3.4.3.2 I²C Boot

When the MSC7110 device is configured to boot from the I^2C port, the boot program configures the GPIO pins shared with the I^2C pins as I^2C pins. The I^2C interface is configured as follows:

- I²C in master mode.
- EPROM in slave mode.

For details on the boot procedure, see the "Boot Program" chapter of the MSC711x Reference Manual.

3.5 DDR Memory System Guidelines

MSC7110 devices contain a memory controller that provides a glueless interface to external double data rate (DDR) SDRAM memory modules with Class 2 Series Stub Termination Logic 2.5 V (SSTL_2). There are two termination techniques, as shown in Figure 32. Technique B is the most popular termination technique.

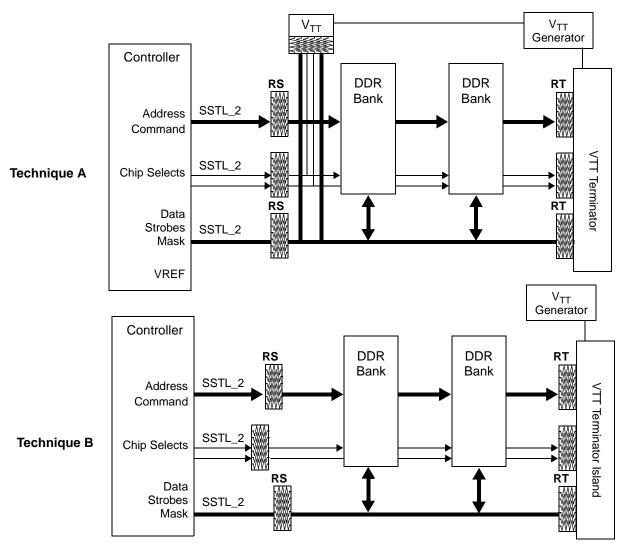


Figure 32. SSTL Termination Techniques

Figure 33 illustrates the power wattage for the resistors. Typical values for the resistors are as follows:

- $RS = 22 \Omega$
- $RT = 24 \Omega$

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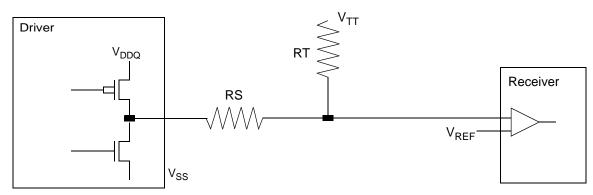


Figure 33. SSTL Power Value

3.5.1 V_{REF} and V_{TT} Design Constraints

 V_{TT} and V_{REF} are isolated power supplies at the same voltage, with V_{TT} as a high current power source. This section outlines the voltage supply design needs and goals:

- Minimize the noise on both rails.
- V_{TT} must track variation in the V_{REF} DC offsets. Although they are isolated supplies, one possible solution is to use a single IC to generate both signals.
- Both references should have minimal drift over temperature and source supply.
- It is important to minimize the noise from coupling onto V_{REF} as follows:
 - Isolate V_{REF} and shield it with a ground trace.
 - Use 15–20 mm track.
 - Use 20–30 mm clearance between other traces for isolating.
 - Use the outer layer route when possible.
 - Use distributed decoupling to localize transient currents and return path and decouple with an inductance less than 3 nH.
- Max source/sink transient currents of up to 1.8 A for a 32-bit data bus.
- Use a wide island trace on the outer layer:
 - Place the island at the end of the bus.
 - Decouple both ends of the bus.
 - Use distributed decoupling across the island.
 - Place SSTL termination resistors inside the V_{TT} island and ensure a good, solid connection.
- Place the V_{TT} regulator as closely as possible to the termination island.
 - Reduce inductance and return path.
 - Tie current sense pin at the midpoint of the island.

3.5.2 Decoupling

The DDR decoupling considerations are as follows:

- DDR memory requires significantly more burst current than previous SDRAMs.
- In the worst case, up to 64 drivers may be switching states.
- Pay special attention and decouple discrete ICs per manufacturer guidelines.
- Leverage V_{TT} island topology to minimize the number of capacitors required to supply the burst current needs of the termination rail.
- See the Micron DesignLine publication entitled *Decoupling Capacitor Calculation for a DDR Memory Channel* (http://download.micron.com/pdf/pubs/designline/3Q00dll-4.pdf).



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3.5.3 General Routing

The general routing considerations for the DDR are as follows:

- All DDR signals must be routed next to a solid reference:
 - For data, next to solid ground planes.
 - For address/command, power planes if necessary.
- All DDR signals must be impedance controlled. This is system dependent, but typical values are 50–60 ohm.
- Minimize other cross-talk opportunities. As possible, maintain at least a four times the trace width spacing between all DDR signals to non-DDR signals.
- Keep the number of vias to a minimum to eliminate additional stubs and capacitance.
- Signal group routing priorities are as follows:
 - DDR clocks.
 - Route MVTT/MVREF.
 - Data group.
 - Command/address.
- Minimize data bit jitter by trace matching.

3.5.4 Routing Clock Distribution

The DDR clock distribution considerations are as follows:

- DDR controller supports six clock pairs:
 - 2 DIMM modules.
 - Up to 36 discrete chips.
- For route traces as for any other differential signals:
 - Maintain proper difference pair spacing.
 - Match pair traces within 25 mm.
- Match all clock traces to within 100 mm.
- Keep all clocks equally loaded in the system.
- Route clocks on inner critical layers.

3.5.5 Data Routing

The DDR data routing considerations are as follows:

- Route each data group (8-bits data + DQS + DM) on the same layer. Avoid switching layers within a byte group.
- Take care to match trace lengths, which is extremely important.
- To make trace matching easier, let adjacent groups be routed on alternate critical layers.
- Pin swap bits within a byte group to facilitate routing (discrete case).
- Tight trace matching is recommended within the DDR data group. Keep each 8-bit datum and its DM signal within ± 25 mm of its respective strobe.
- Minimize lengths across the entire DDR channel:
 - Between all groups maintain a delta of no more than 500 mm.
 - Allows greater flexibility in the design for readjustments as needed.
- DDR data group separation:
 - If stack-up allows, keep DDR data groups away from the address and control nets.
 - Route address and control on separate critical layers.
 - If resistor networks (RNs) are used, attempt to keep data and command lines in separate packages.



Ordering Information

3.6 Connectivity Guidelines

This section summarizes the connections and special conditions, such as pull-up or pull-down resistors, for the MSC7110 device. Following are guidelines for signal groups and configuration settings:

- Clock and reset signals.
 - SWTE is used to configure the MSC7110 device and is sampled on the deassertion of PORESET, so it should be tied to V_{DDC} or GND either directly or through pull-up or pull-down resistors until PORESET is deasserted. After PORESET, this signal can be left floating.
 - BM[0-1] configure the MSC7110 device and are sampled until PORESET is deasserted, so they should be tied to V_{DDIO} or GND either directly or through pull-up or pull-down resistors.
 - HRESET should be pulled up.
- Interrupt signals. When used, IRQ pins must be pulled up.
- HDI16 signals.
 - When they are configured for open-drain, the HREQ/HREQ or HTRQ/HTRQ signals require a pull-up resistor. However, these pins are also sampled at power-on reset to determine the HDI16 boot mode and may need to be pulled down. When these pins must be pulled down on reset and pulled up otherwise, a buffer can be used with the HRESET signal as the enable.
 - When the device boots through the HDI16, the HDDS, HDSP and H8BIT pins should be pulled up or down, depending on the required boot mode settings.
- I^2C signals. The SCL and SDA signals, when programmed for I^2C , requires an external pull-up resistor.
- General-purpose I/O (GPIO) signals. An unused GPIO pin can be disconnected. After boot, program it as an output pin.
- · Other signals.
 - The $\overline{\mathsf{TEST0}}$ pin must be connected to ground.
 - The TPSEL pin should be pulled up to enable debug access via the EOnCE port and pulled down for boundary scan.
 - Pins labelled NO CONNECT (NC) must not be connected.
 - When a 16-pin double data rate (DDR) interface is used, the 16 unused data pins should be no connects (floating) if the used lines are terminated.
 - Do not connect DBREQ to DONE (as you would for the MSC8101 device). Connect DONE to one of the EVNT pins, and DBREQ to HRRQ.

4 Ordering Information

Consult a Freescale Semiconductor sales office or authorized distributor to determine product availability and place an order.

Part	Supply Voltage	Package Type	Pin Count	Core Frequency (MHz)	Solder Spheres	Order Number
MSC7110 (mask	1.2 V core 2.5 V mem.	Molded Array Process-Ball Grid Array (MAP-BGA)	400	200	Lead-free	MSC7110VM800
1L44X	3.3 V I/O	Trinay (Wirth BOTY)			Lead-bearing	MSC7110VF800
MSC7110 (mask	1.2 V core 2.5 V mem	Molded Array Process-Ball Grid Array (MAP-BGA)	400	266	Lead-free	MSC7110VM1000
1M88B)	3.3 V I/O	Allay (MAI -DOA)			Lead-bearing	MSC7110VF1000



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5 Package Information

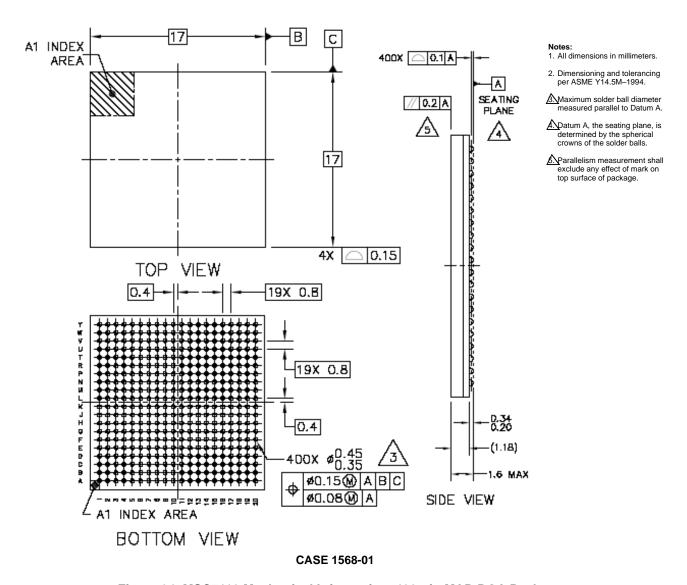


Figure 34. MSC7110 Mechanical Information, 400-pin MAP-BGA Package

6 Product Documentation

- *MSC711x Reference Manual* (MSC711xRM). Includes functional descriptions of the extended cores and all the internal subsystems including configuration and programming information.
- Application Notes. Cover various programming topics related to the StarCore DSP core and the MSC7110 device.
- *SC140/SC1400 DSP Core Reference Manual*. Covers the SC140 and SC1400 core architecture, control registers, clock registers, program control, and instruction set.

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Revision History

7 Revision History

Table 33 provides a revision history for this data sheet.

Table 33. Document Revision History

Revision	Date	Description
0	Apr 2004	Initial public release.
1	May 2004	Added ordering information and new package options.
2	Aug. 2004	 Updated clock parameter values. Updated DDR timing specifications. Updated I²C timing specifications.
3	Sep. 2004	 Updated Figures 1-2 and 1-2 to correct HDSP and DBREQ. Corrected EE0 port reference. Updated ball location for HDSP.
4	Jan. 2005	 Added signal HA3. Updated absolute maximum ratings, DDR DRAM capacitance specifications, clock parameters, reset timing, and TDM timing. Added note for timing reference for I²C interface. Expanded GPIO timing information. Corrected pin T20 and K20 signal designation. Corrected signal names to GPAO15 and IRQ2. Expanded design guidelines in Chapter 4.
5	Mar. 2005	 Updated features list. Updated power specifications. Changed CLKIN frequency range. Added clock configuration information. Updated JTAG timings.
6	Apr. 2005	Added recommended power supply ratings and updated equations to estimate power consumption.
7	Oct. 2005	Updated core and total power consumption examples.
8	Dec. 2005	 Added information about signals GPIOA16, GPIOA17, GPIOA27, GPIOA28, and GPIOA29 to signal description and pinout location lists.
9	Nov. 2006	 Updated Reference Manual reference to MSC711x Reference Manual. Updated arrows in Host DMA Writing Timing figure. Updated boot overview.
10	Aug. 2007	 Updated to new data sheet format. Reorganized and renumbered sections, figures, and tables. Added a note to clarify the definition of TCK timing 700 in new Table 31. The power-up and power-down sequences have been expanded to five possible design scenarios/cases. These cases replace the previously recommended power-up/power-down sequence recommendations. The section has been clarified by adding subsection headings.
11	Apr 2008	• Change the PLL filter resistor from 20 Ω to 2 Ω in Section 3.2.5.

MSC7110 Low-Cost 16-bit DSP with DDR Controller Data Sheet, Rev. 11



Datasheet of MSC7110VM800 - IC DSP PROCESSOR 16BIT 400MAPBGA

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